

Ce qui sera étudié

ANALOGIQUE

Le courant continu

Le volt

L'ampere

L'ohm

Le watt

Les résistances

Les diodes

Les condensateurs

Les transistors

L ampli opérationnel

Les circuits intégrés

Le courant alternatif

Le transformateur

Les relais

Les moteurs

Les hauts parleurs

Les générateurs de signaux(oscillateurs)

Les inducteurs

Les selfs

Les circuits LC, RC, RLC

Les filtres PH, PB

Les antennes

NUMERIQUES

Binaire, octal, hexa, ascii

Les portes et, ou, nand, nor

La logique combinatoire

L'unité arithmétique et logiques

Les memoires

Les registres

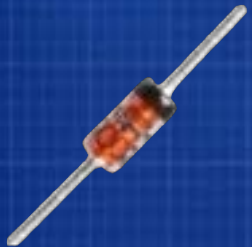
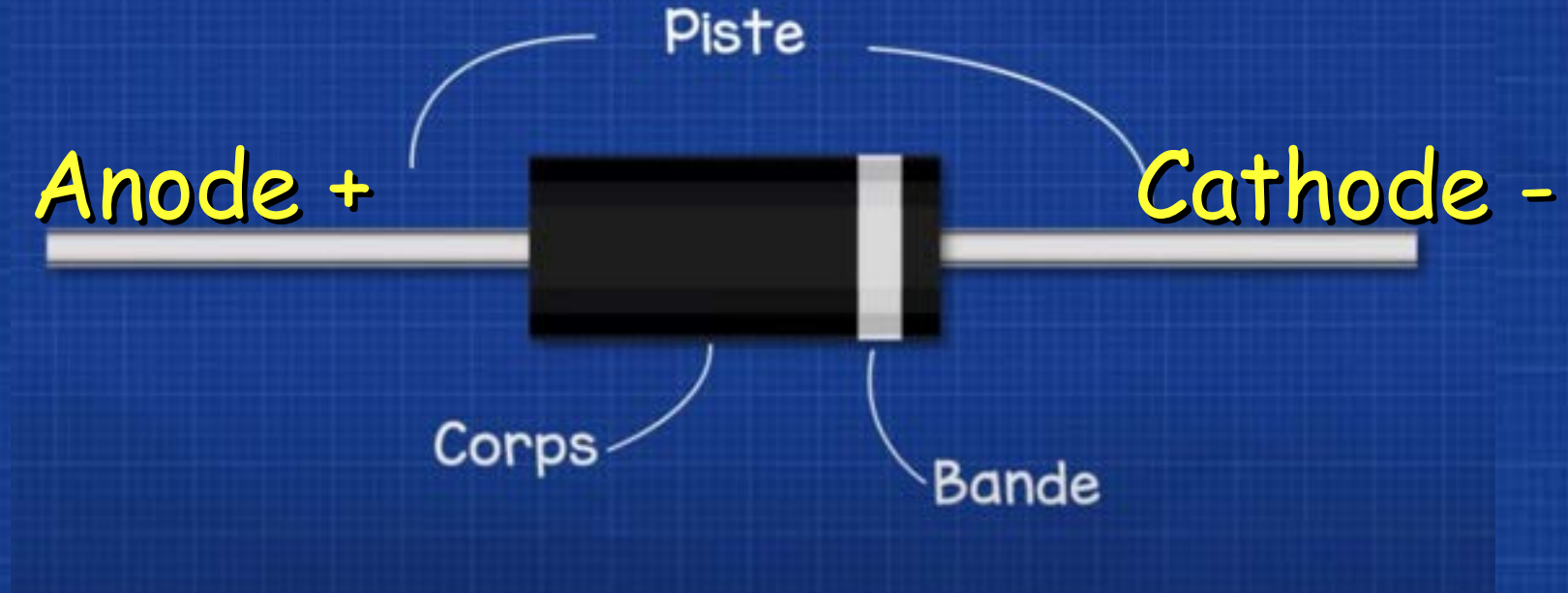
Les processeurs

Les micro controleurs

On comprend - On réalise - On expérimente

LES DIODES

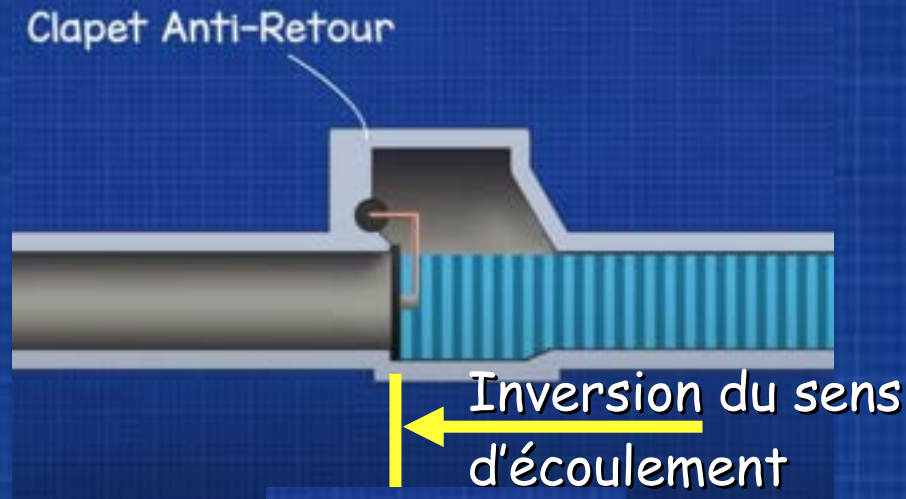
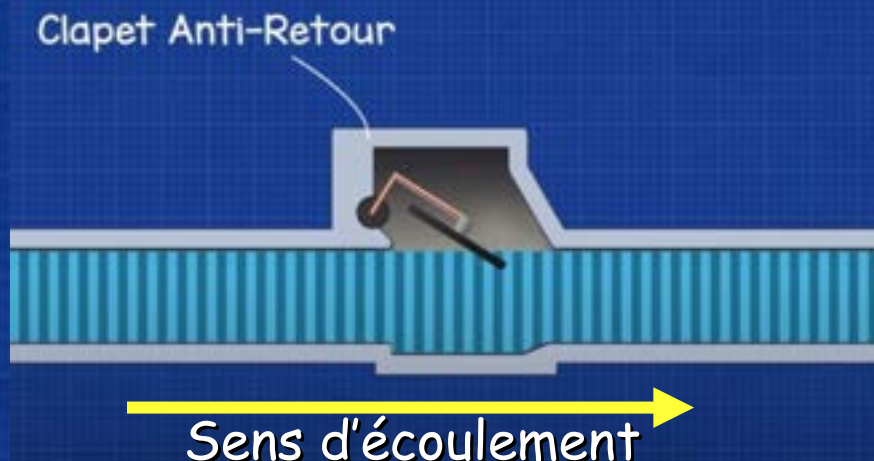
La DIODE est un semi-conducteur



Schottky, Laser, Photodiode, Gunn, PIN, effet tunnel,.....

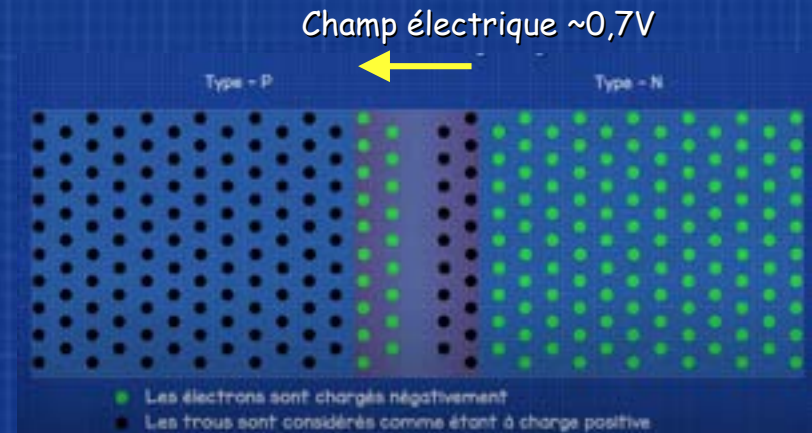
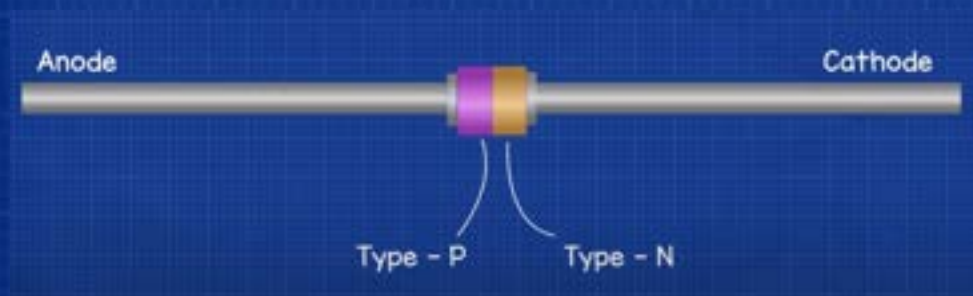
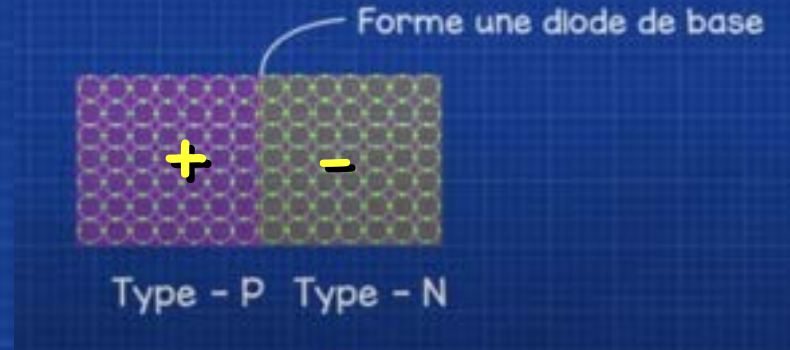
LES DIODES

Principe



LES DIODES

Conception



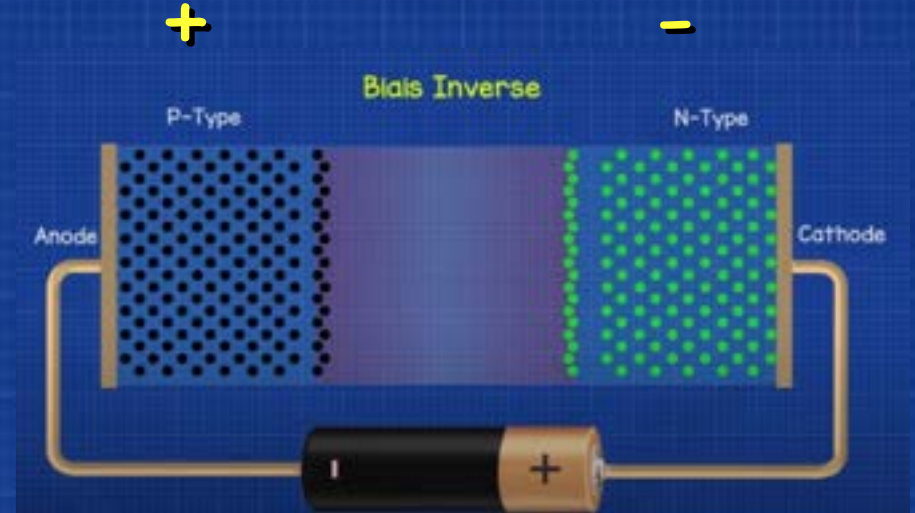
LES DIODES

Conception



passante

Le courant circule



bloquée

Le courant ne circule pas

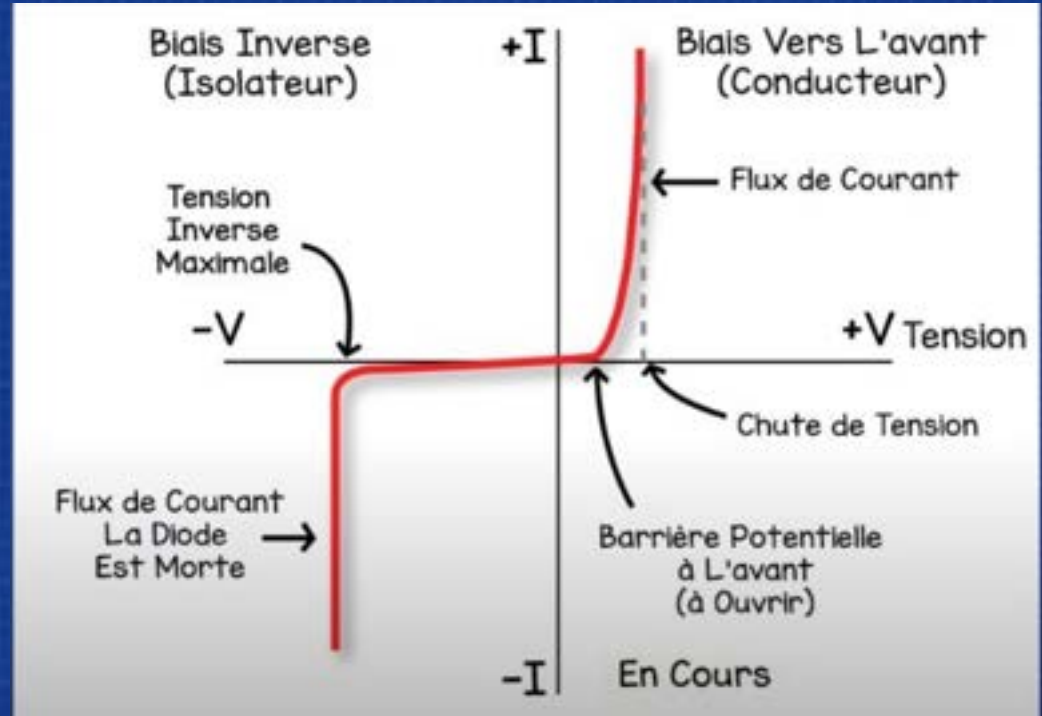
Il faut que la tension soit supérieure a 0,7V

LES DIODES

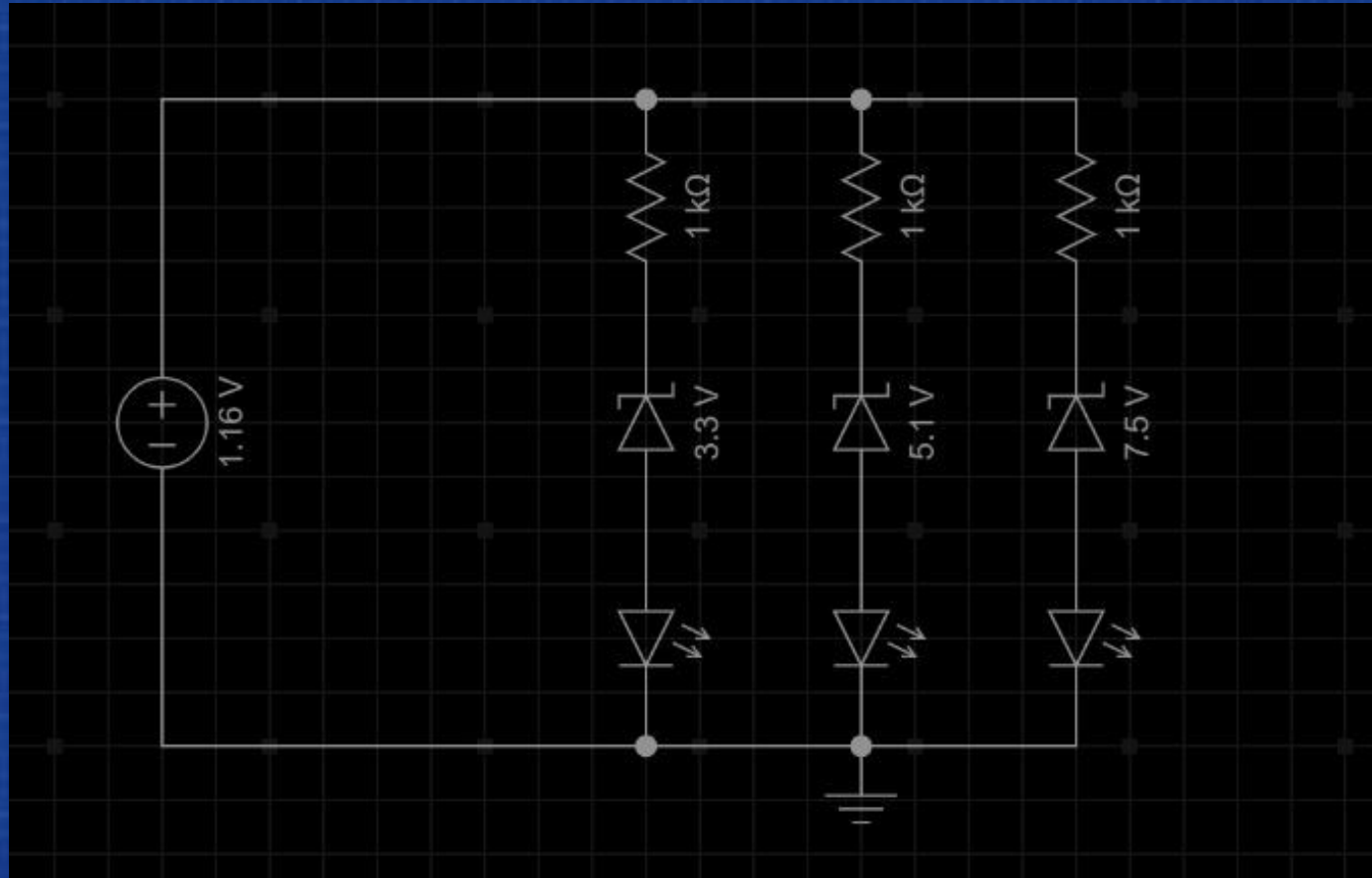
Caractéristiques :



- Protéger des circuits sur l'inversion de polarité
- Redresser le courant (alternatif en continu)
- Séparer le signal en fréquence de la composante continu
- Matrice a diode



Montage avec des diodes zener (Voltmetre)



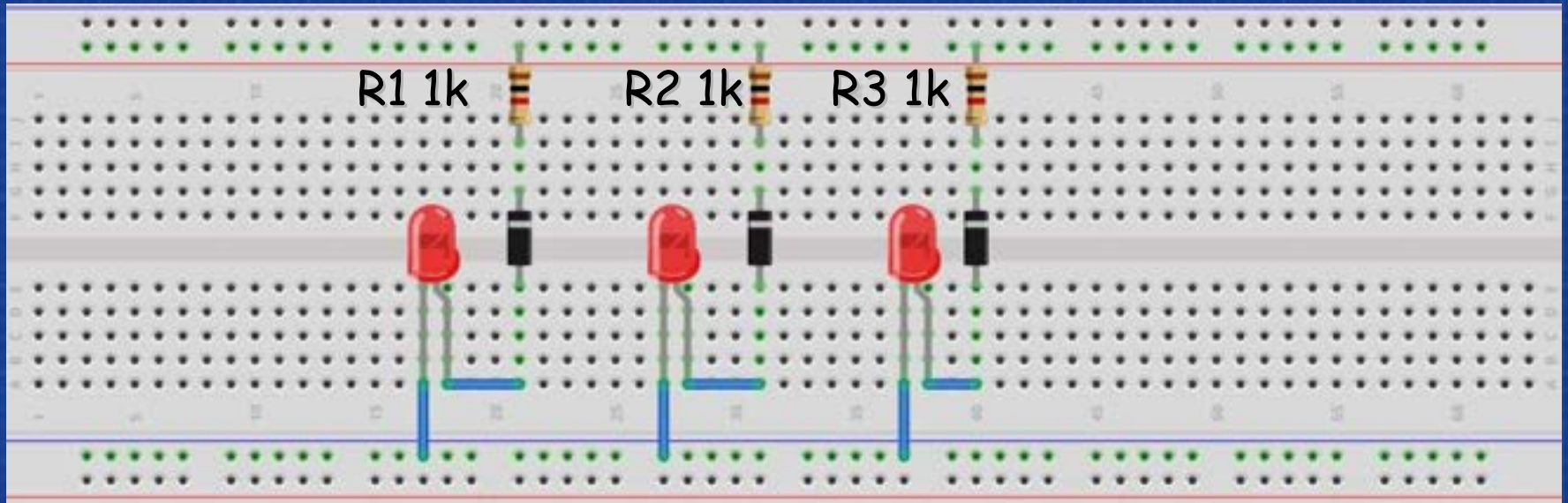
Que se passe t-il si on fait varier la tension d'alimentation ?

Montage avec des diodes zener (Voltmetre)

Zener 1
1N4728

Zener 2
1N4733

Zener 3
1N4737



Que se passe t-il si on fait varier la tension d'alimentation ?



LES CONDENSATEURS

L'unité est le **FARAD**

Le symbole **F** ou **μF**

Ses caractéristiques :

Sa capacité en μF

Sa tension max en V



Condensateur



Condensateur
Polarisé



Condensateur
Polarisé



Condensateur
Variable



Condensateur
Potentiomètre

LES CONDENSEURS

Condensateur



Stockage
d'énergie

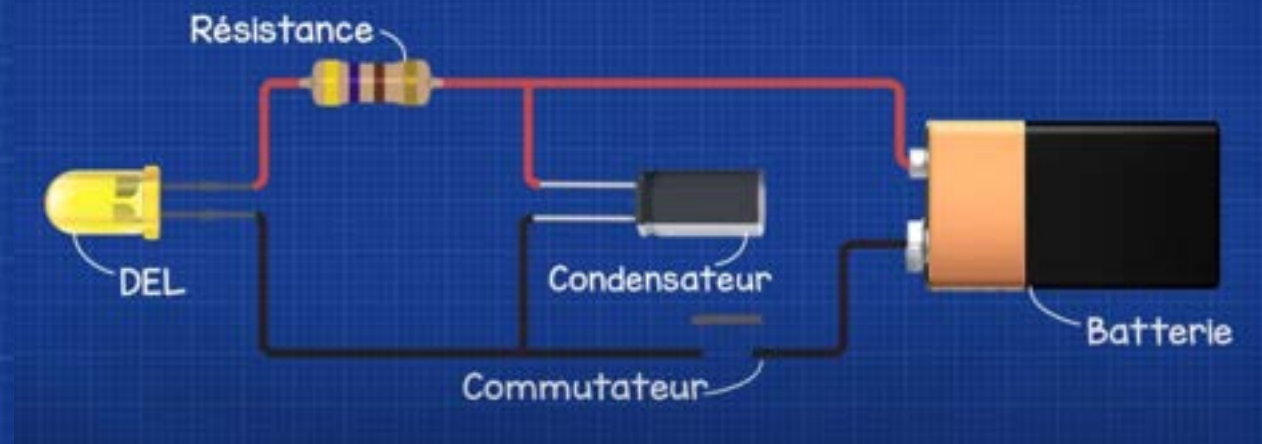
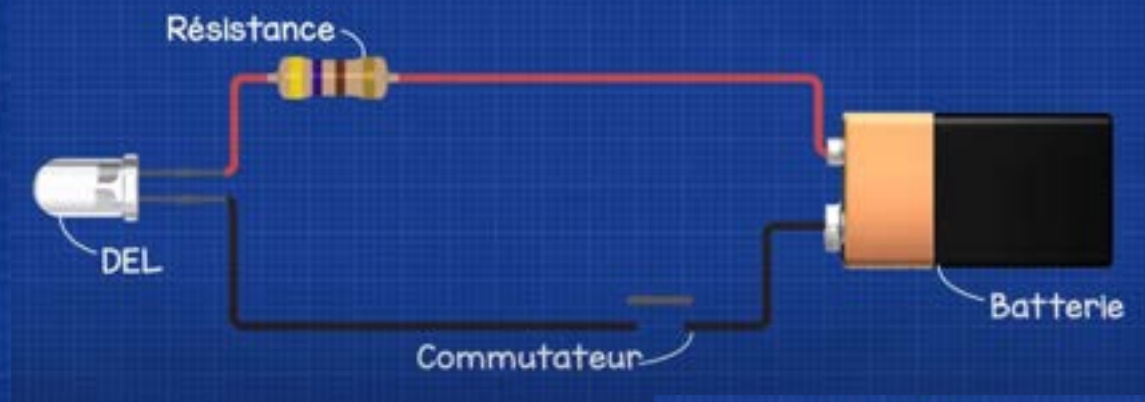
Champ électrique

Batterie

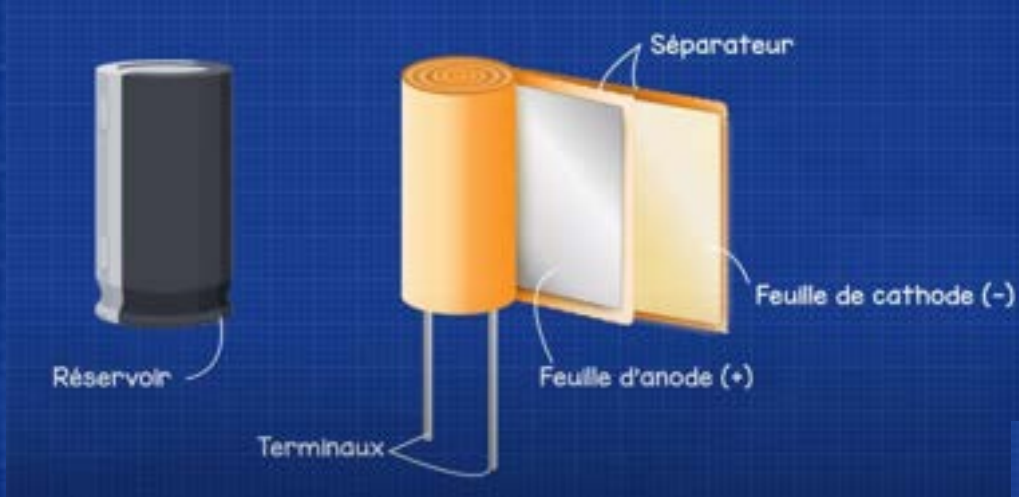


Chimique

LES CONDENSATEURS

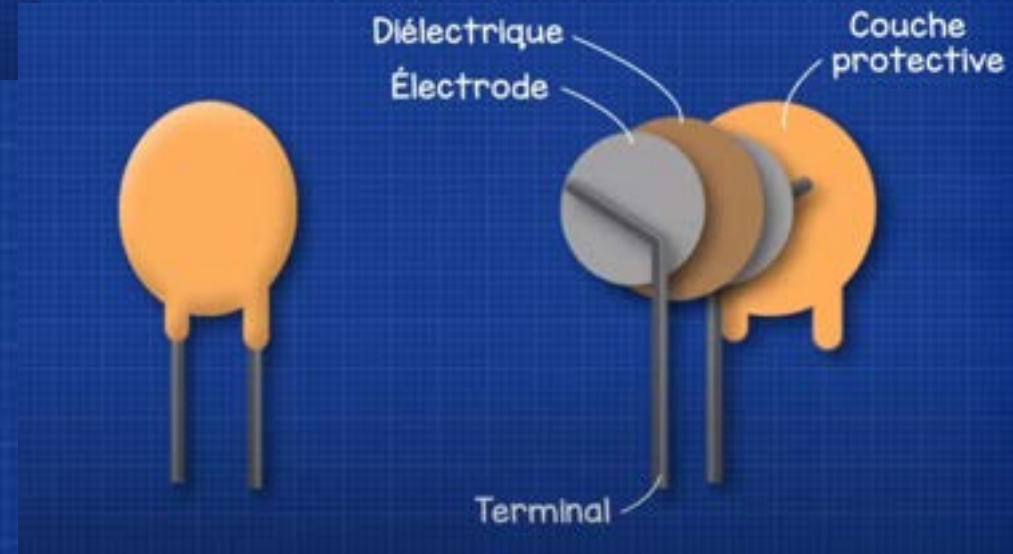


LES CONDENSATEURS

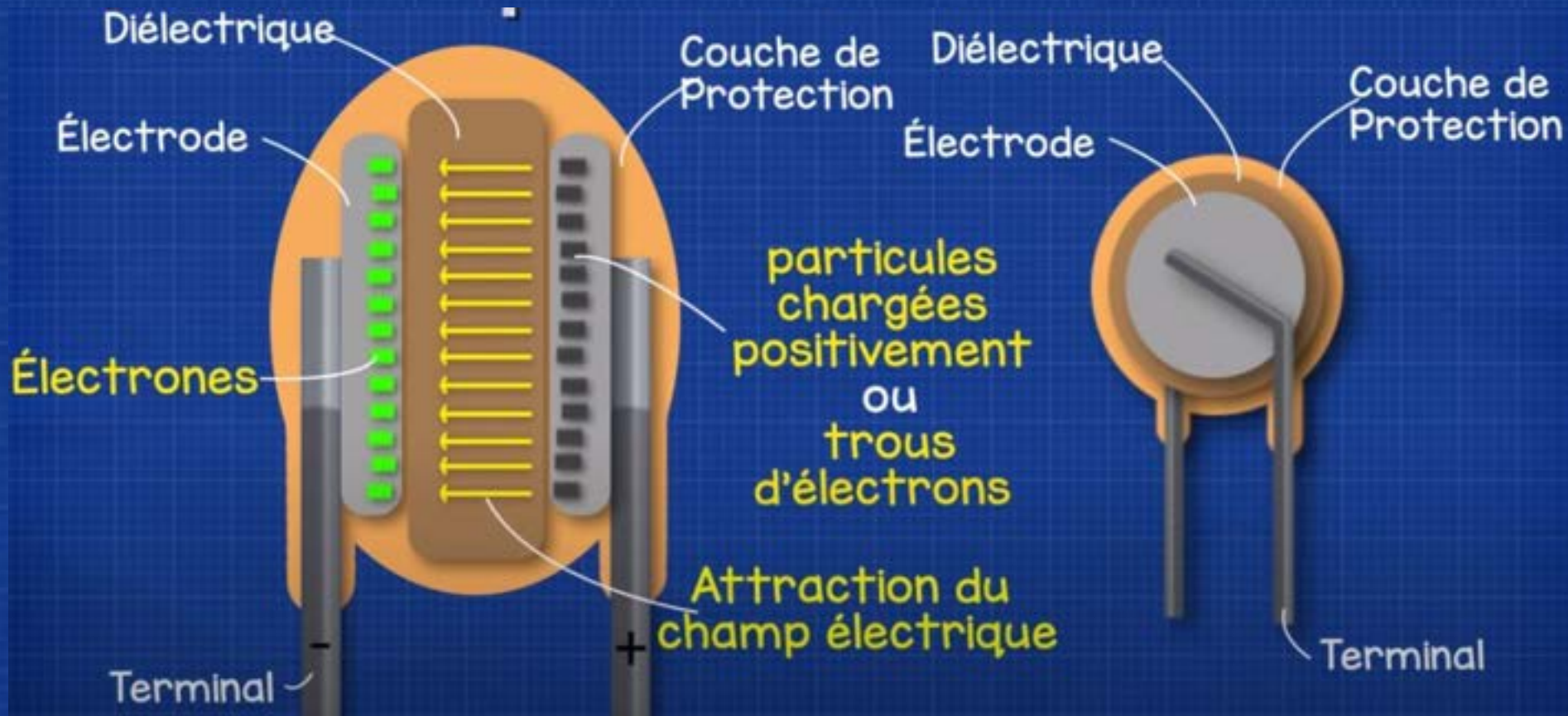


Condensateur électrolytique
(polarisé)

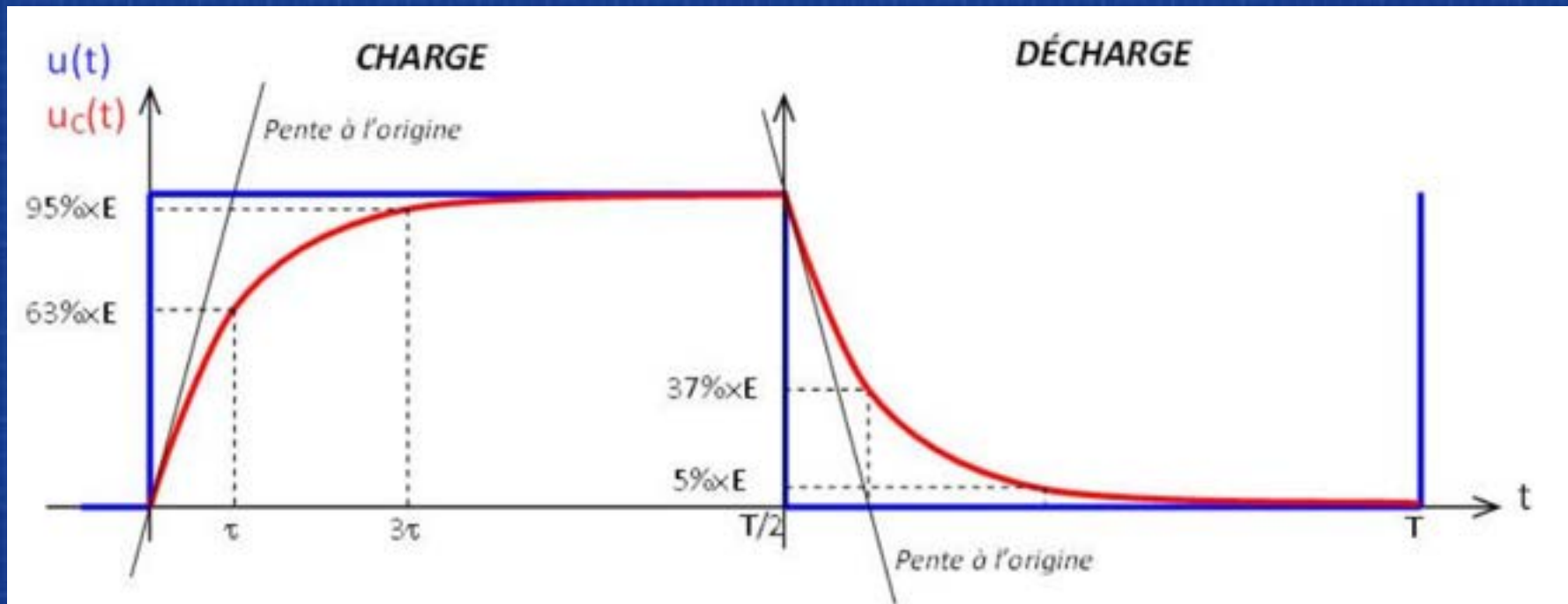
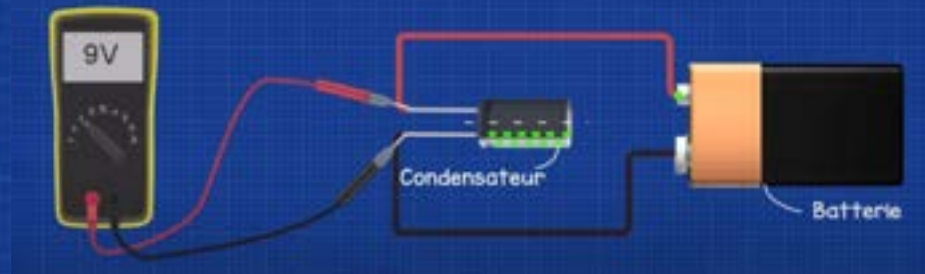
Condensateur tantale Ou goutte



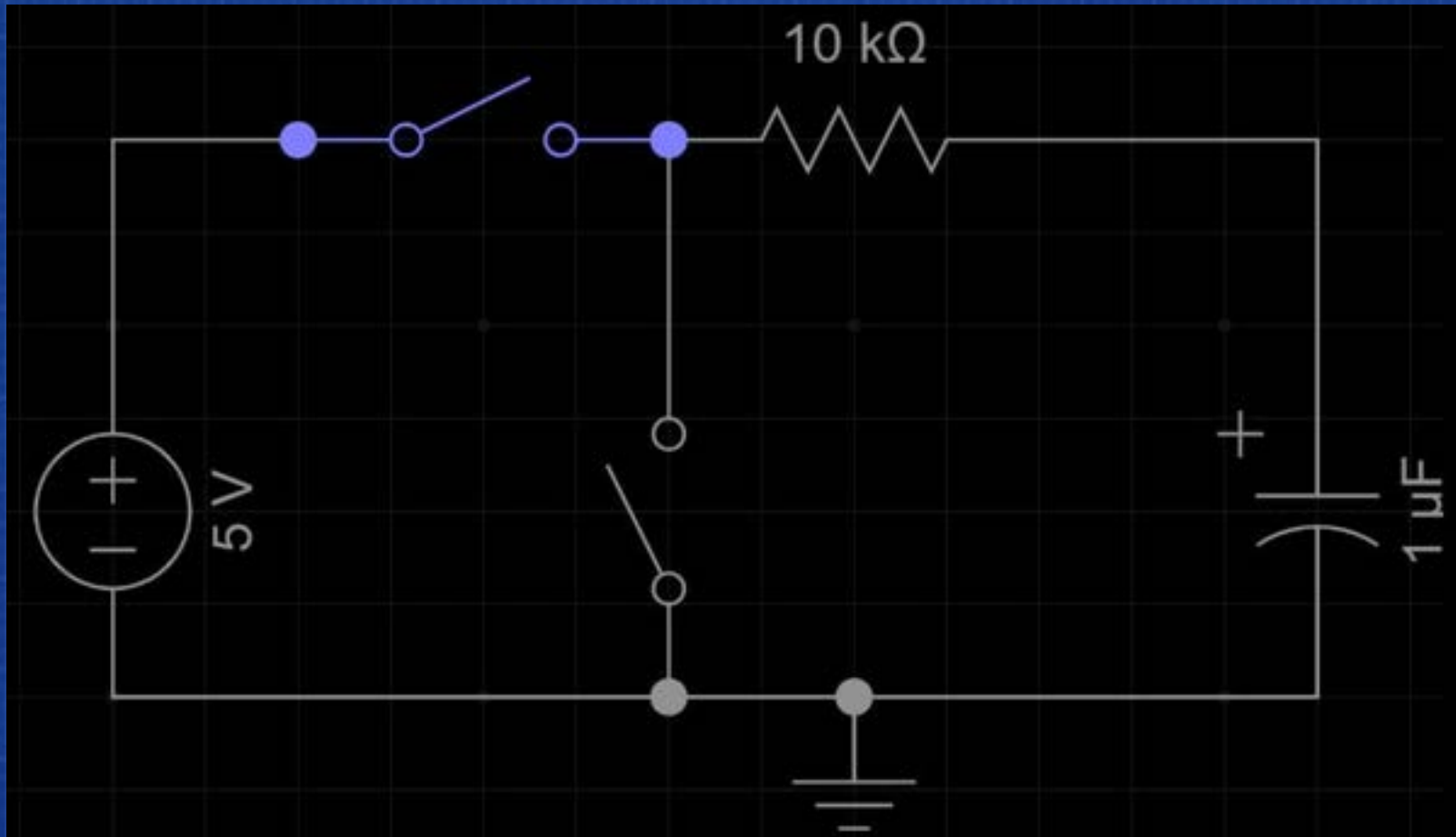
LES CONDENSATEURS



LES CONDENSATEURS



LES CONDENSATEURS

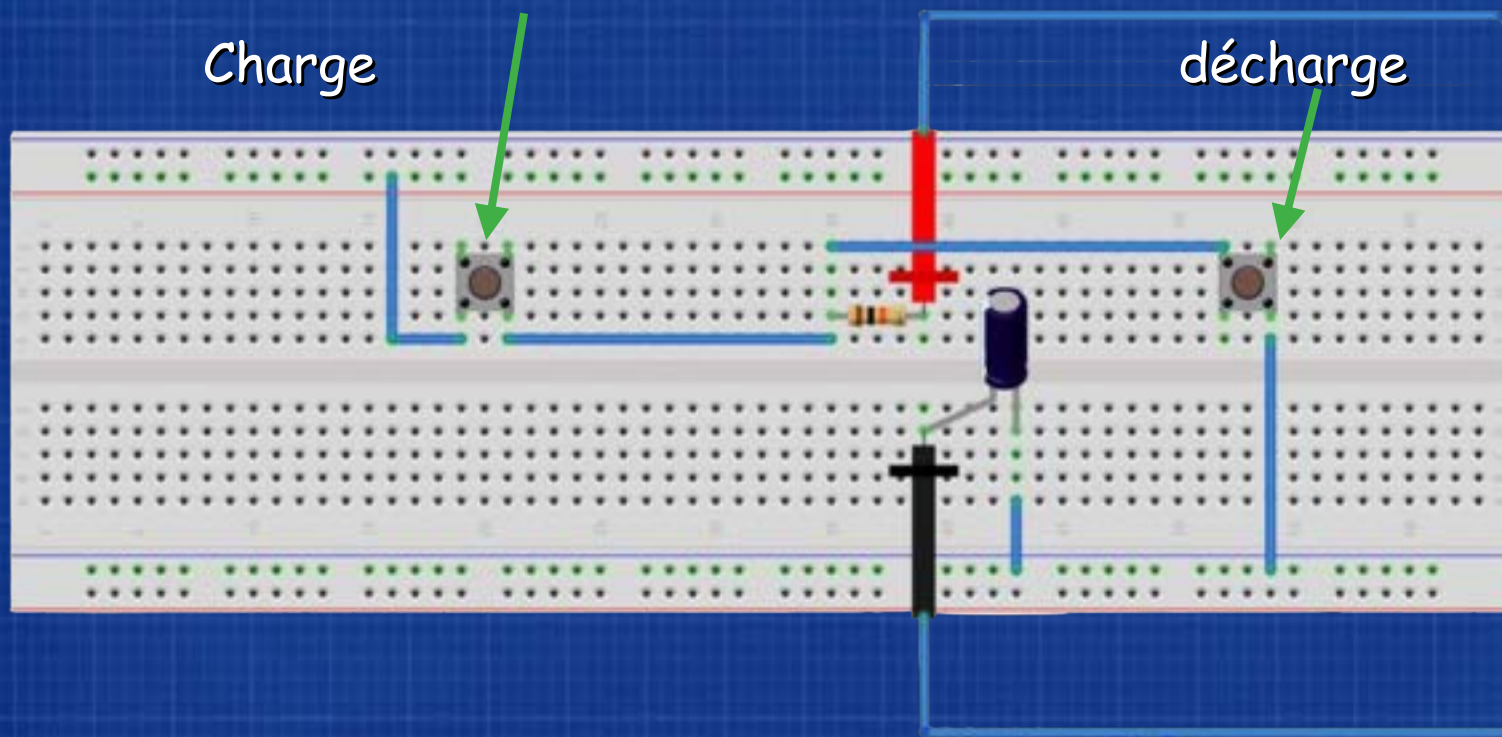


LES CONDENSATEURS

On commute d'abord ce poussoir

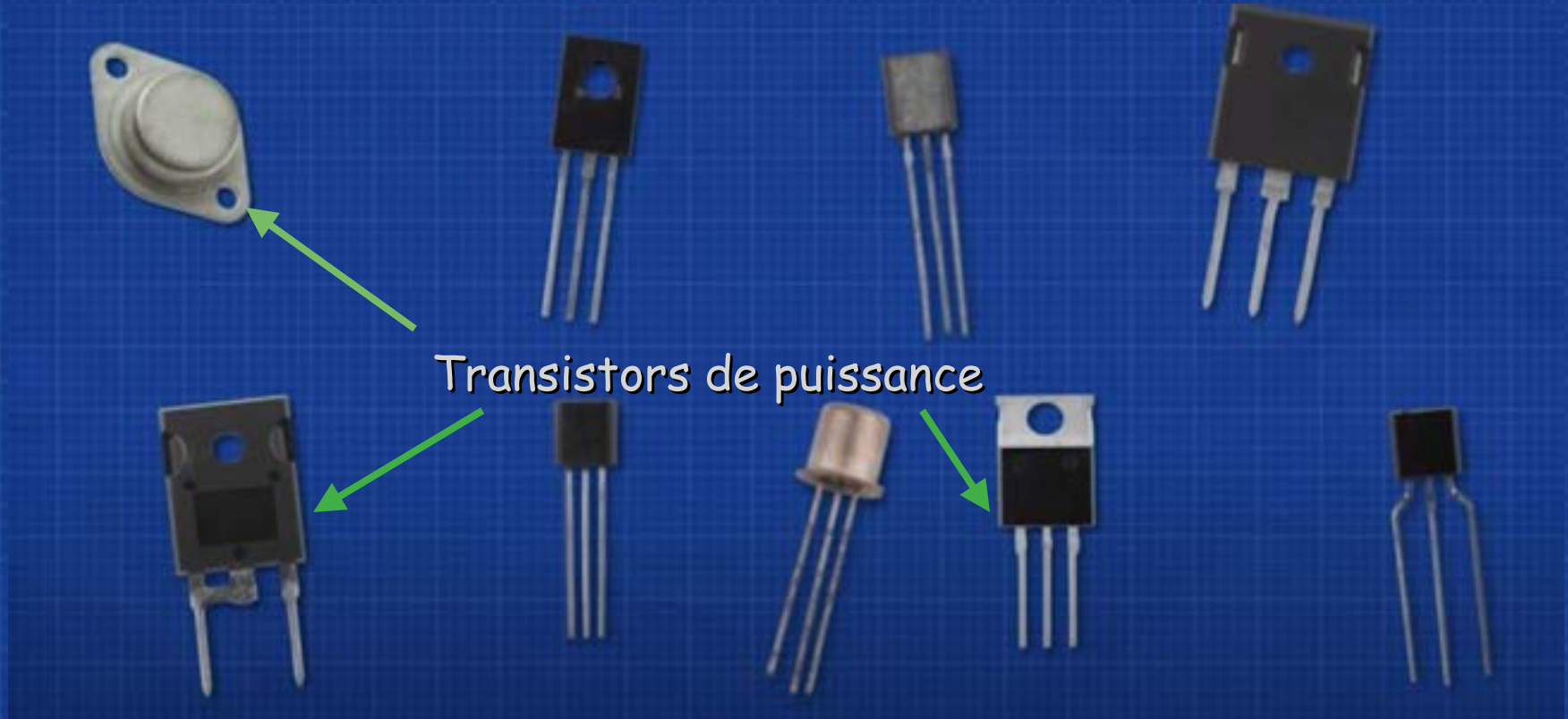
Charge

décharge



LES TRANSISTORS

Différents packagings



LES TRANSISTORS



Bipolaire

Simple - Darlington



Effet de champ

JFET - MOSFET

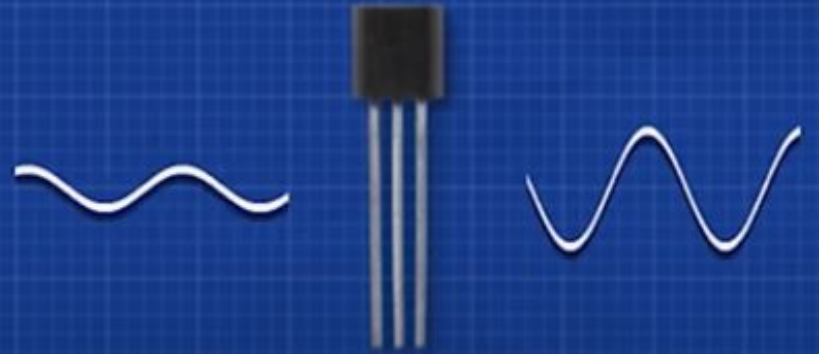
LES TRANSISTORS

Utilisation en commutation



Allumer et éteindre
les circuits

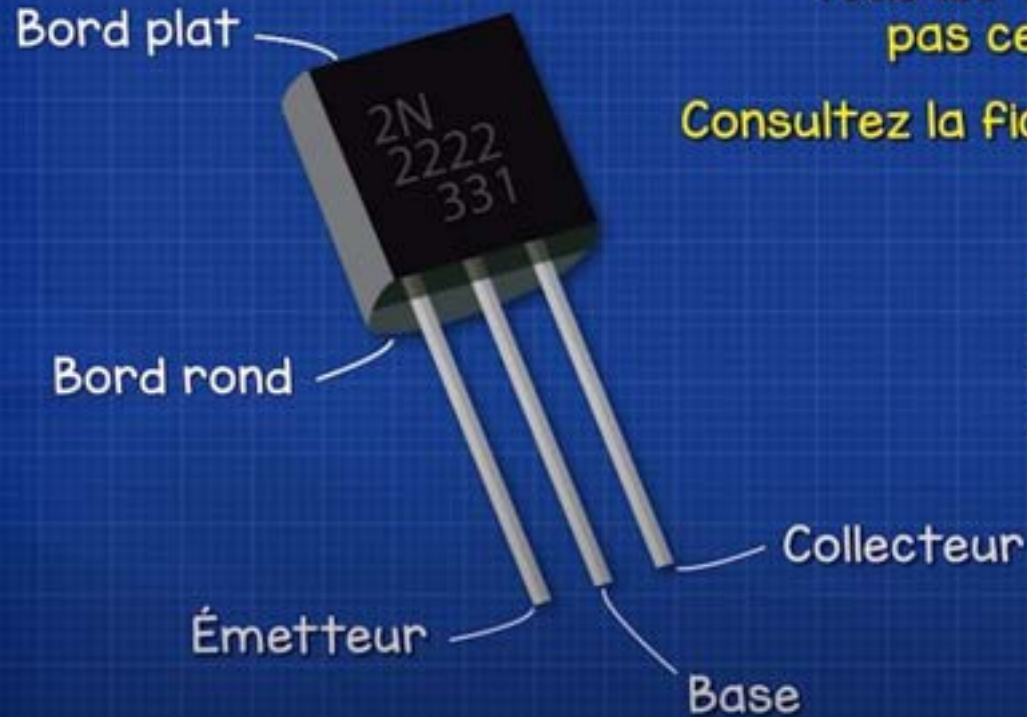
Utilisation en amplification



Amplifier les signaux

LES TRANSISTORS

Configuration typique

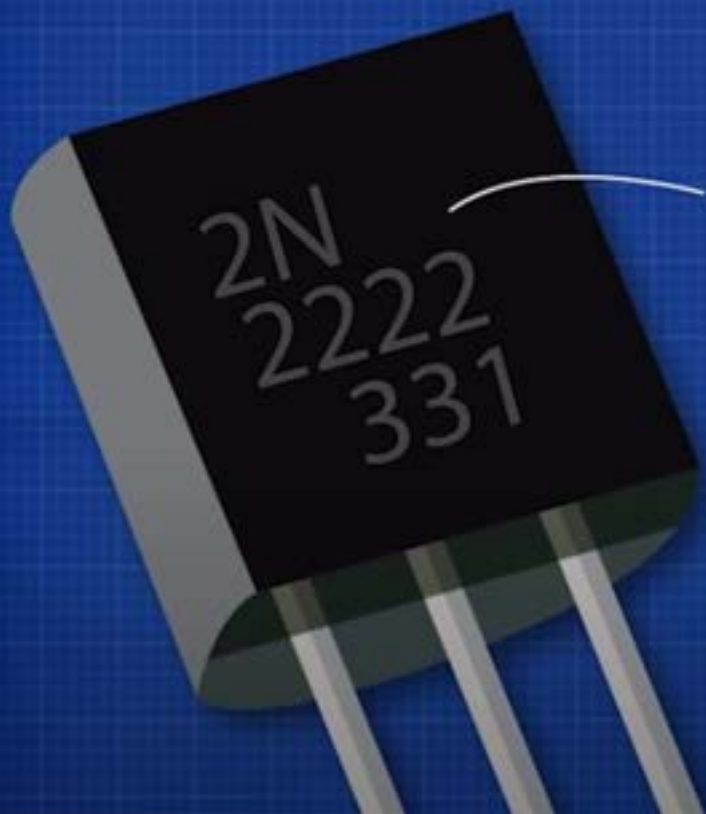


Tous les transistors n'utilisent pas cette configuration

Consultez la fiche technique du fabricant

Émetteur
Base
Collecteur

LES TRANSISTORS




Numéro d'article

Fiche technique
des fabricants

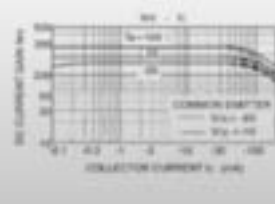
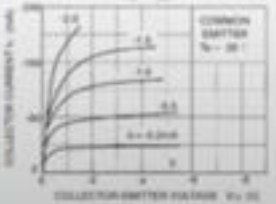
MAXIMUM RATINGS ($T_c=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CE}	Collector-Emitter Voltage	30	V
$V_{CE(sat)}$	Collector-Emitter Voltage	30	V
V_{BE}	Emitter-Base Voltage	5	V
I_C	Collector Current (Continuous)	100	mA
P_C	Collector Power Dissipation	625	mW
T_j	Junction Temperature	175	$^\circ\text{C}$
T_{stg}	Storage Temperature	-65-125	$^\circ\text{C}$



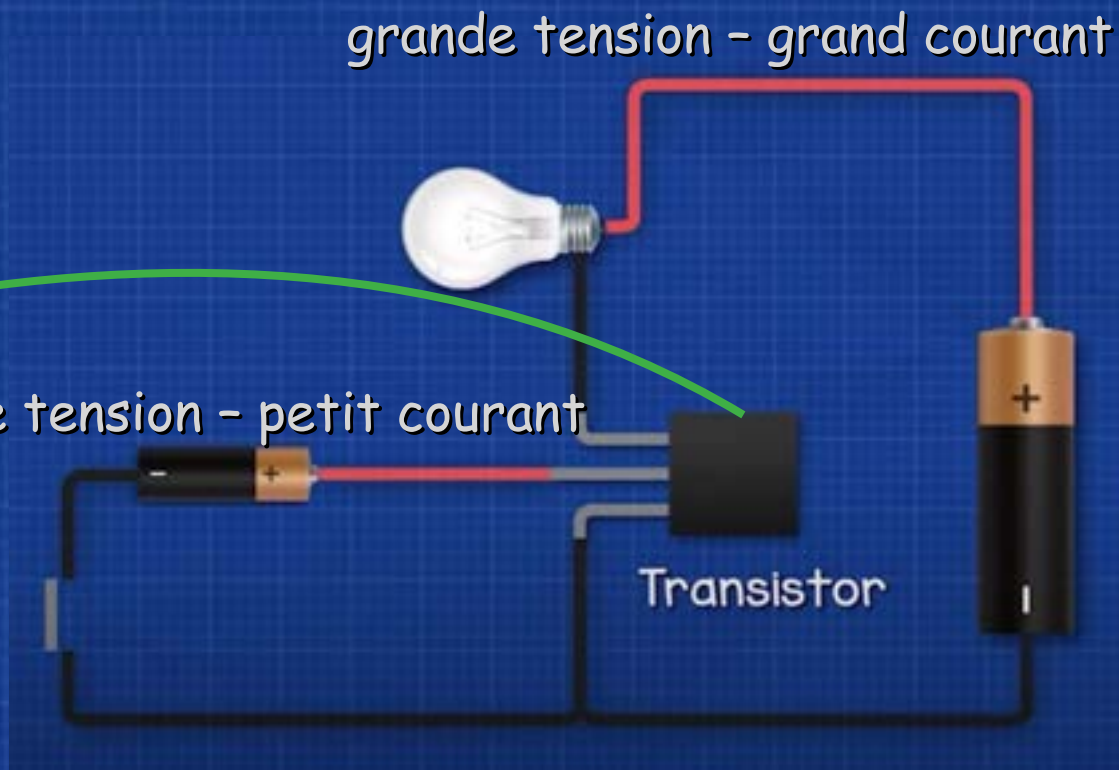
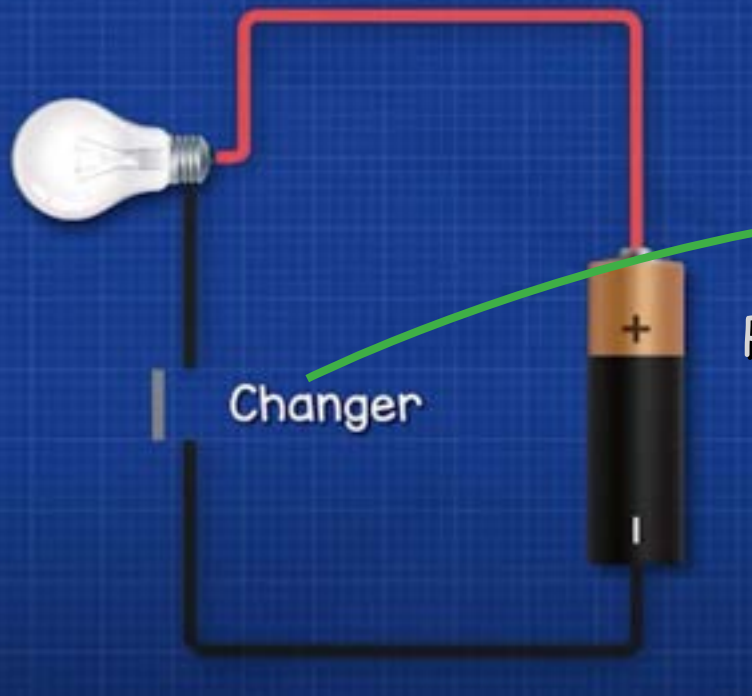
Electrical Characteristics ($T_c=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Collector-Emitter breakdown voltage	$V_{CE(sat)}$	$V_{BE}=0, I_C=0$	30			V
Collector-Emitter saturation voltage	$V_{CE(sat)}$	$V_{BE}=0, I_C=I_C$	0.2			V
Emitter-Base breakdown voltage	V_{BE}	$V_{CE}=0, I_E=0$	5			V
Collector cut-off current	I_{CBO}	$V_{CE}=30, V_{BE}=0$		0.1		μA
Collector saturation current	I_{CS}	$V_{CE}=30, V_{BE}=0$		0.1		μA
Emitter cut-off current	I_{EBO}	$V_{CE}=30, V_{BE}=0$		0.1		μA
DC current gain	β_{DC}	$V_{CE}=30, I_C=10$	10	100		
Collector-Emitter saturation voltage	$V_{CE(sat)}$	$V_{BE}=0, I_C=10$	0.2			V
Base-Emitter saturation voltage	V_{BE}	$V_{CE}=30, I_C=10$	0.7			V
Transition frequency	f_T	$V_{CE}=30, I_C=10$	30		400	MHz
Collector Output Capacitance	C_{ob}	$V_{CE}=30, I_C=10$	1		2	pF
Power Figure	PF	$V_{CE}=30, I_C=10$	5		30	



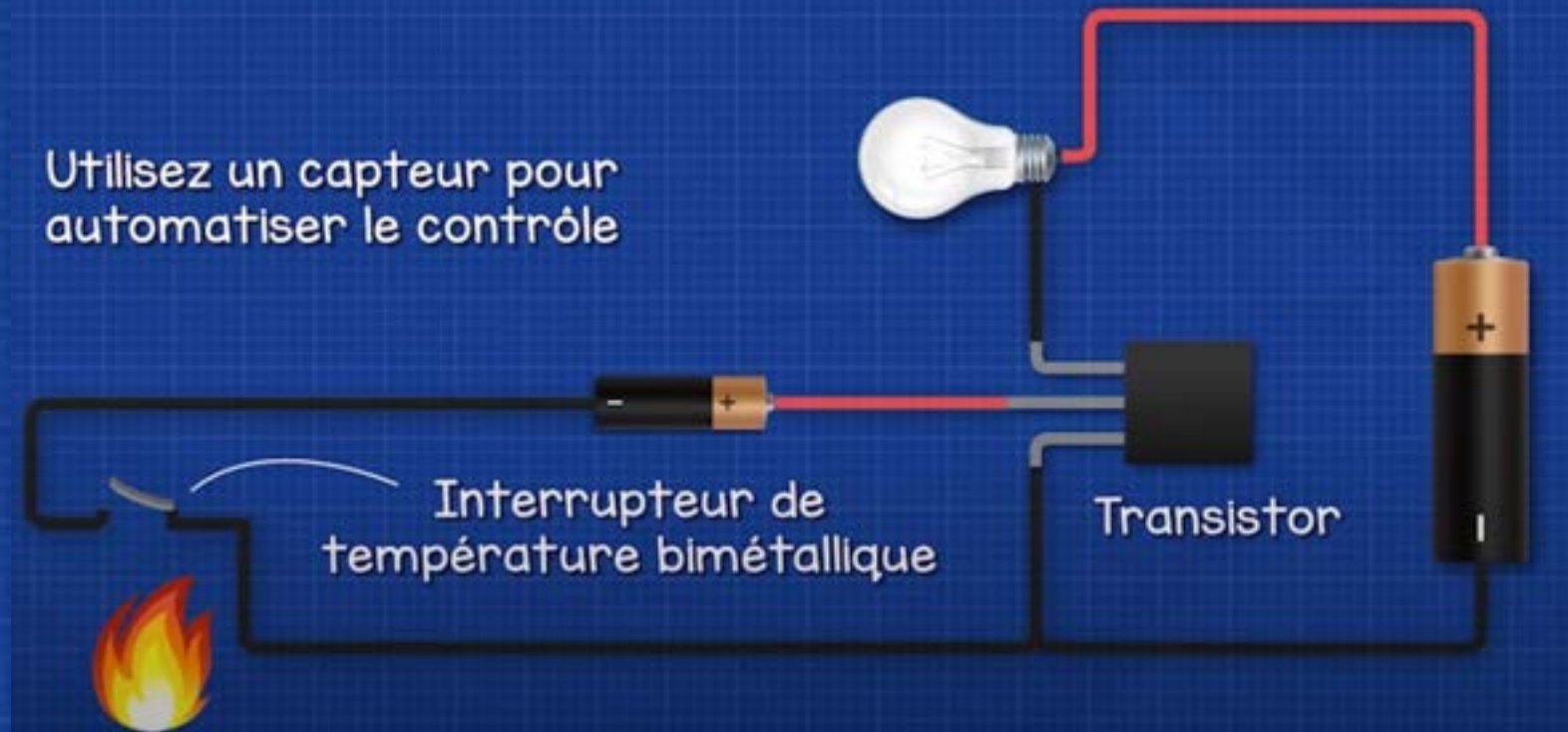
LES TRANSISTORS

Utilisation en commutation



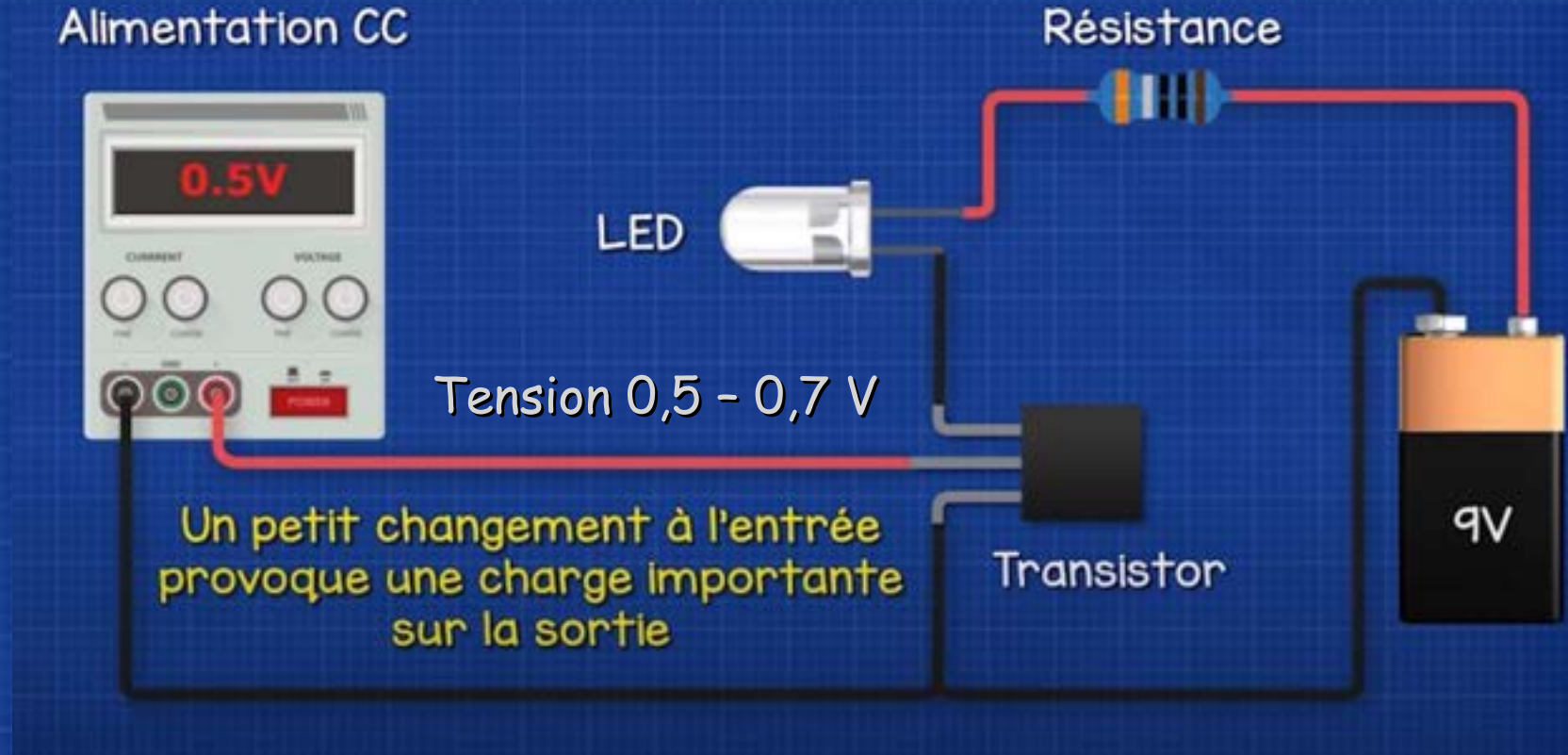
LES TRANSISTORS

Utilisation en commutation



LES TRANSISTORS

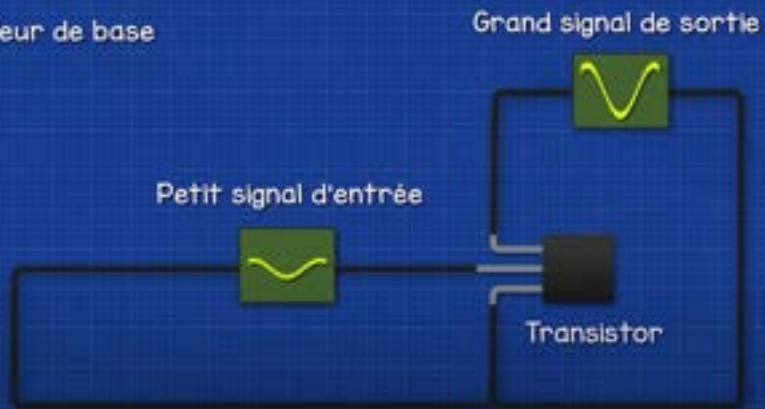
Utilisation en commutation



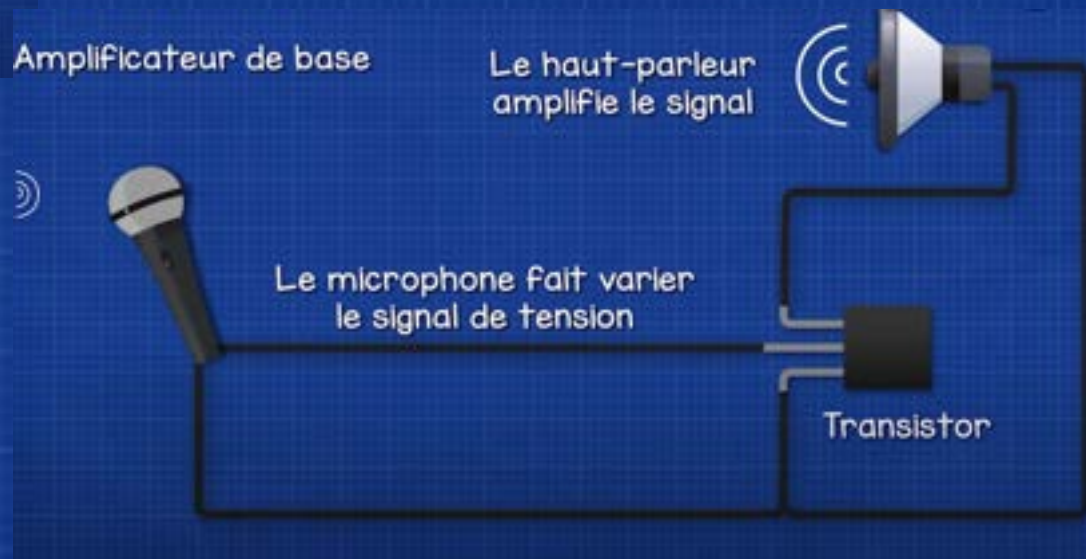
LES TRANSISTORS

Utilisation en amplification

Amplificateur de base



Amplificateur de base



LES TRANSISTORS

NPN

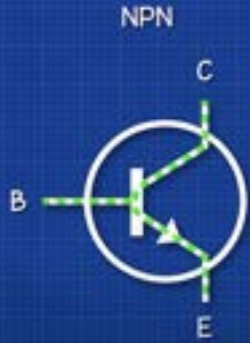


PNP

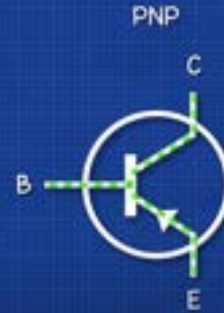


Sont identiques alors
vérifiez le numéro de pièce

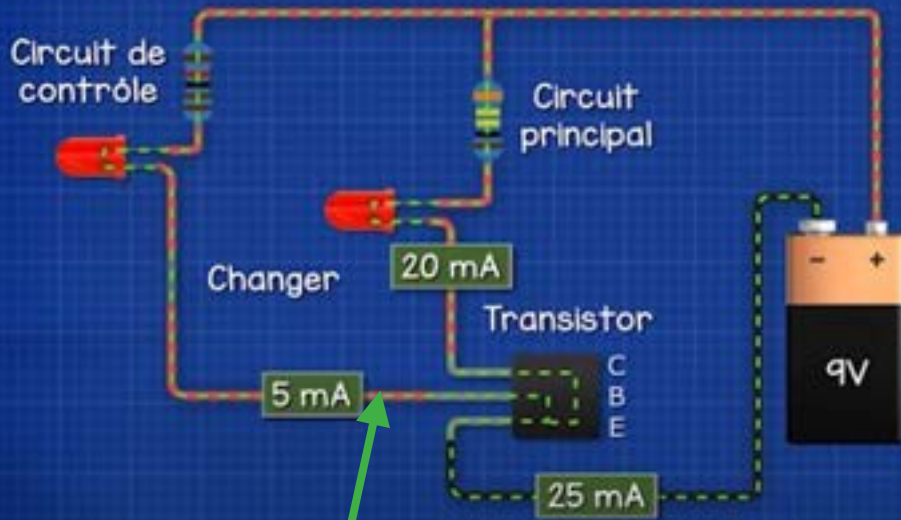
LES TRANSISTORS



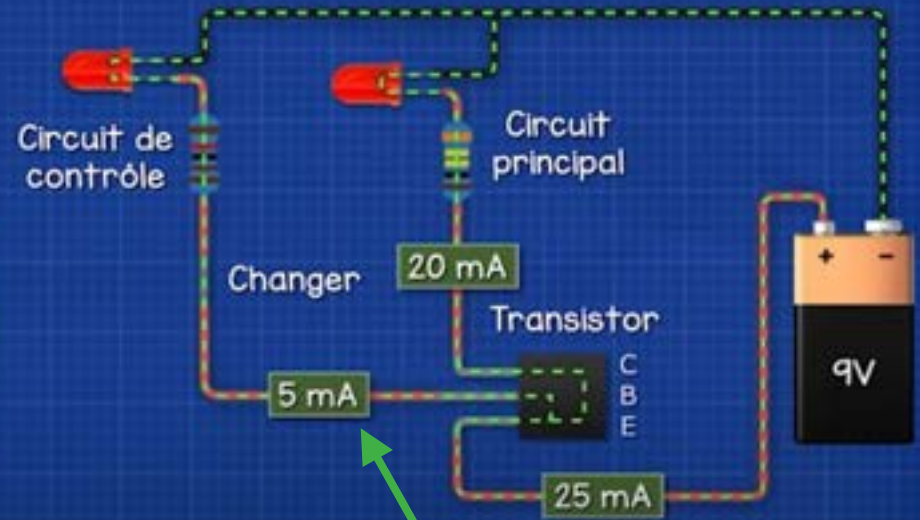
NPN



PNP



Le signal d'entrée est un signal positif (arbitraire)



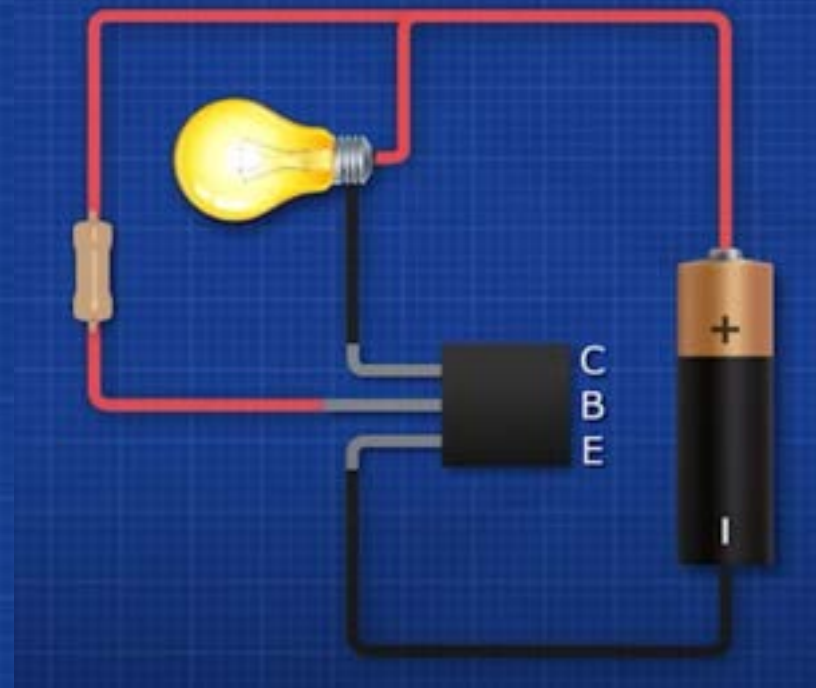
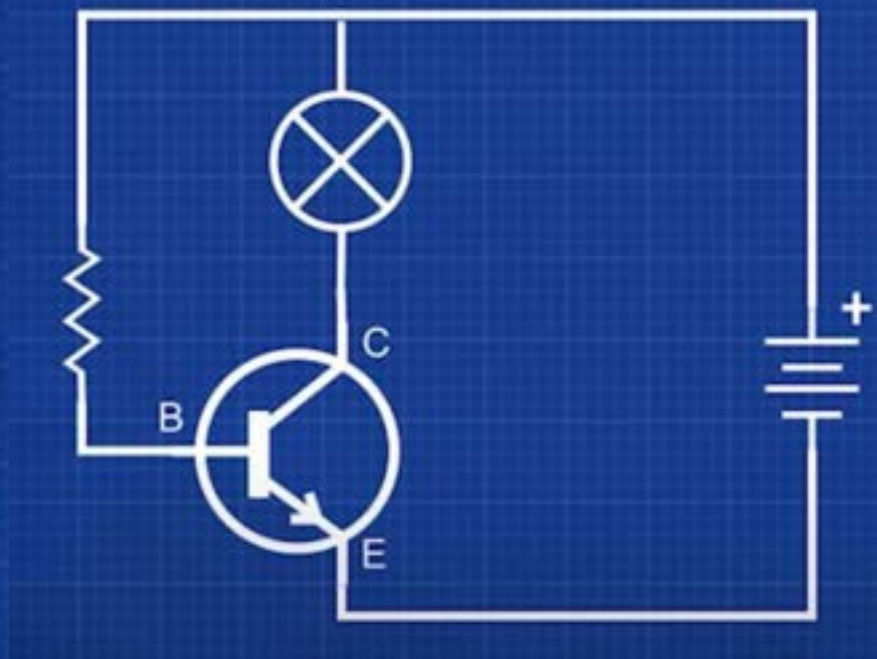
Le signal d'entrée est un signal négatif

LES TRANSISTORS



Comparaison avec un circuit d'eau

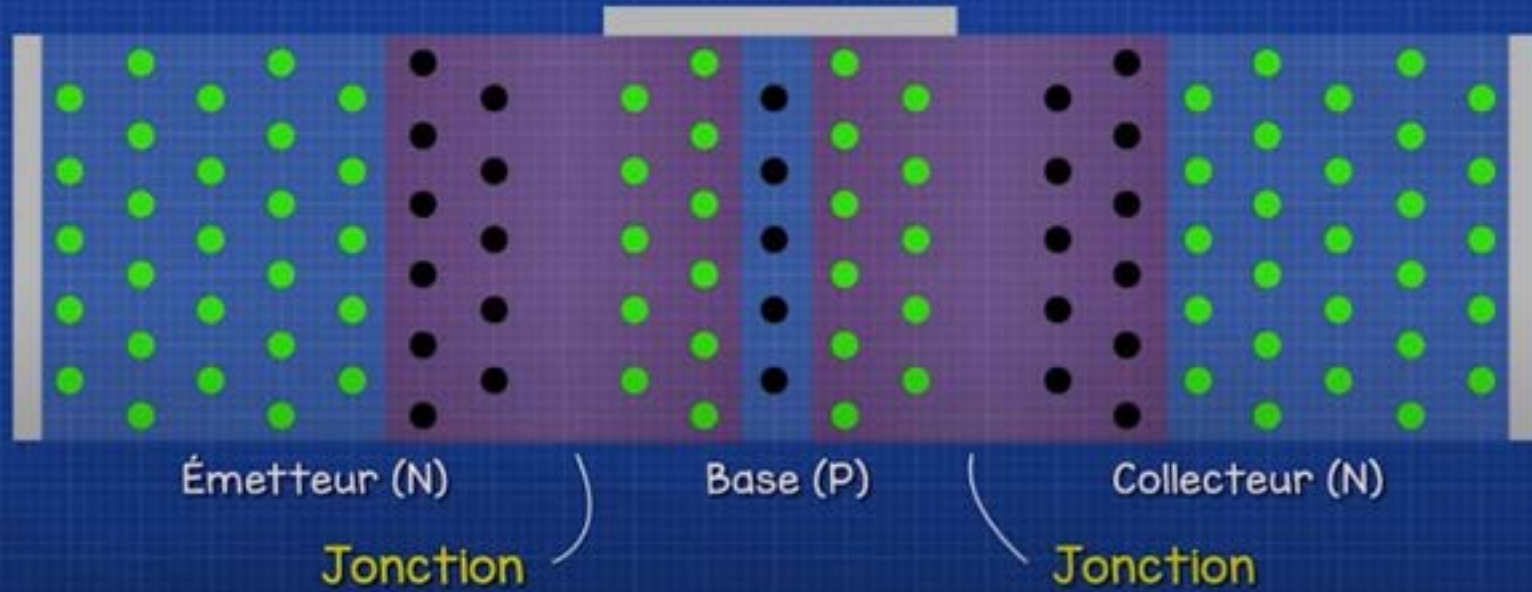
LES TRANSISTORS



Représentaion schématique

LES TRANSISTORS

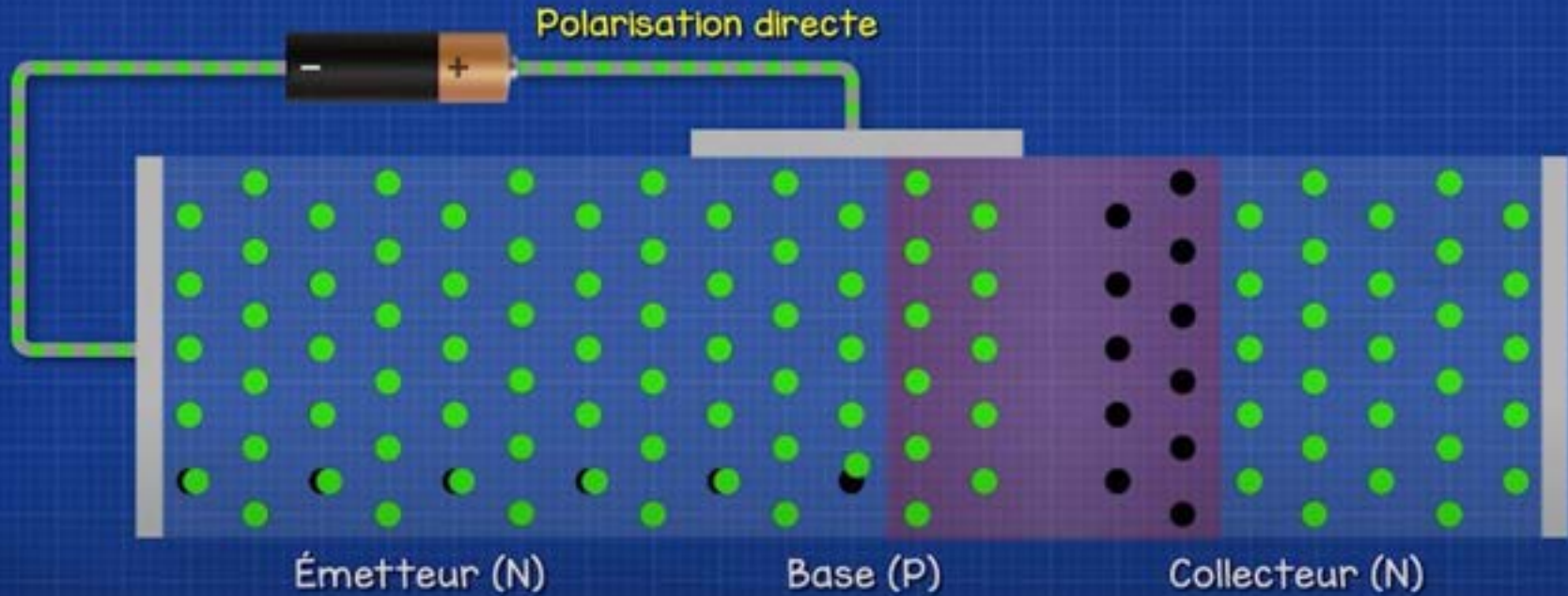
Transistor NPN



Polarisation interne

LES TRANSISTORS

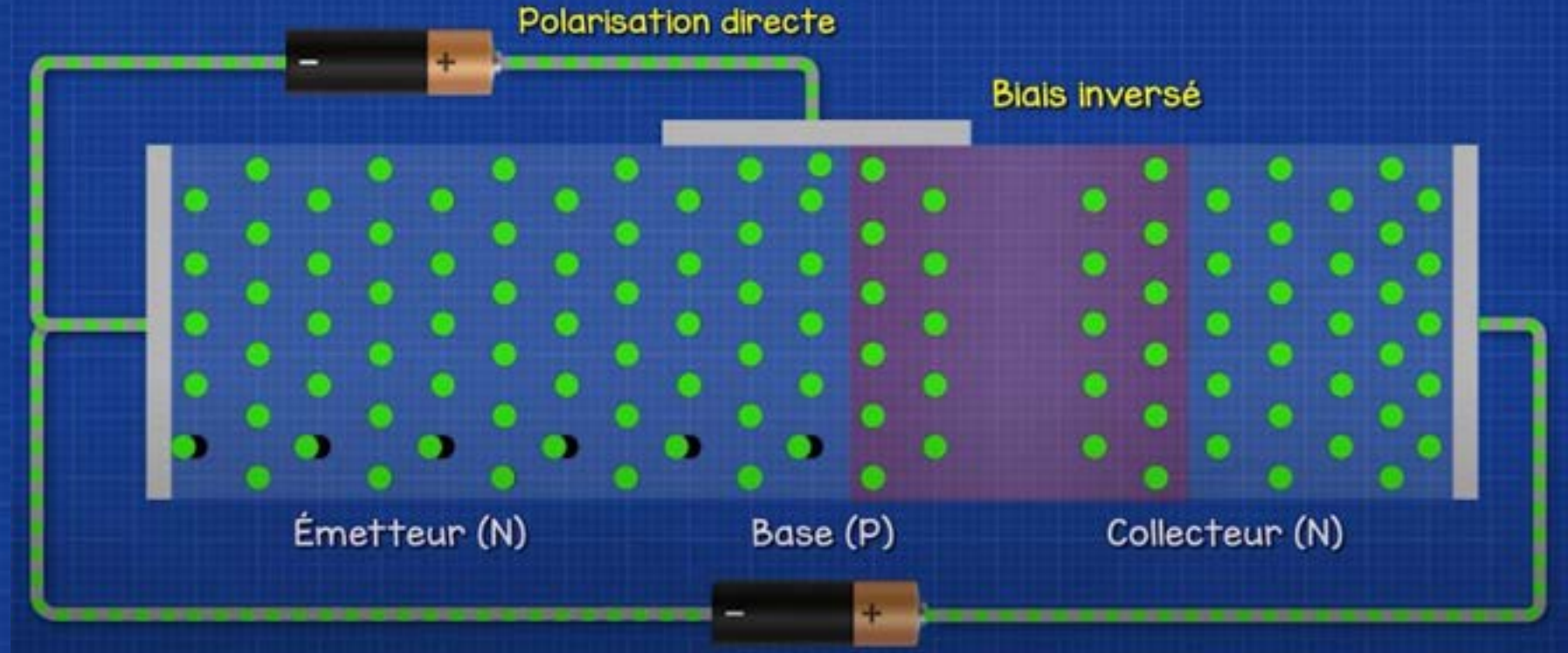
Transistor NPN



Polarisation interne

LES TRANSISTORS

Transistor NPN



Polarisation interne

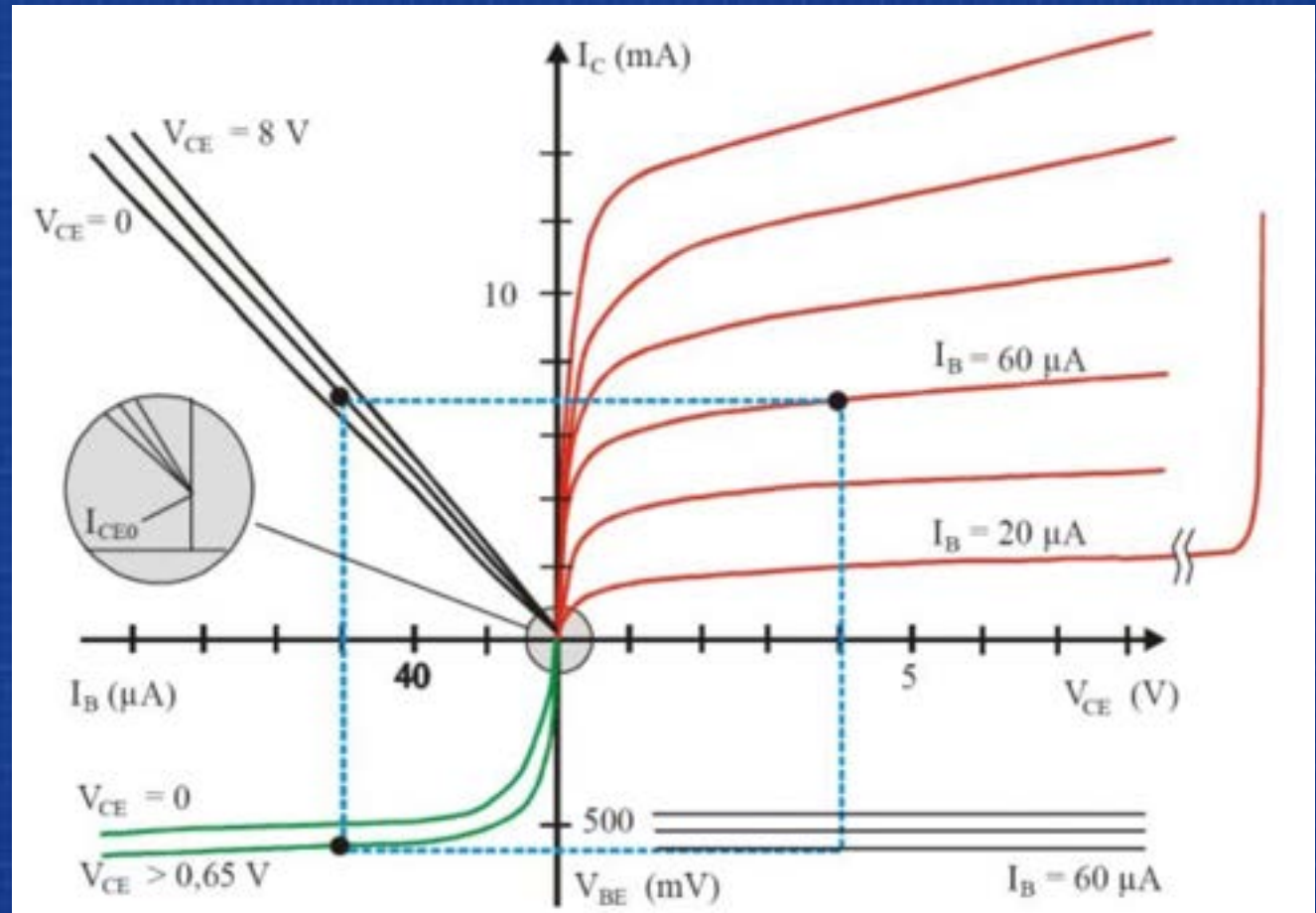
LES TRANSISTORS

$$I_c = \beta I_b$$

$$I_e = I_c + I_b$$

β Béta = gain
(amplification) en
courant

Aussi appelé **HFE**
Hybrid parameter **F**orward
current gain common **E**mitter



LES TRANSISTORS

Tension C-E $V_{CEO} = 40V$
 Tension B-E $V_{EBO} = 6V$
 Courant C – E $I_{CEX} = 10\mu A$
 Courant B – E $I_{BEX} = 20 nA$

Gain HFE (β) max 100

PN2222A

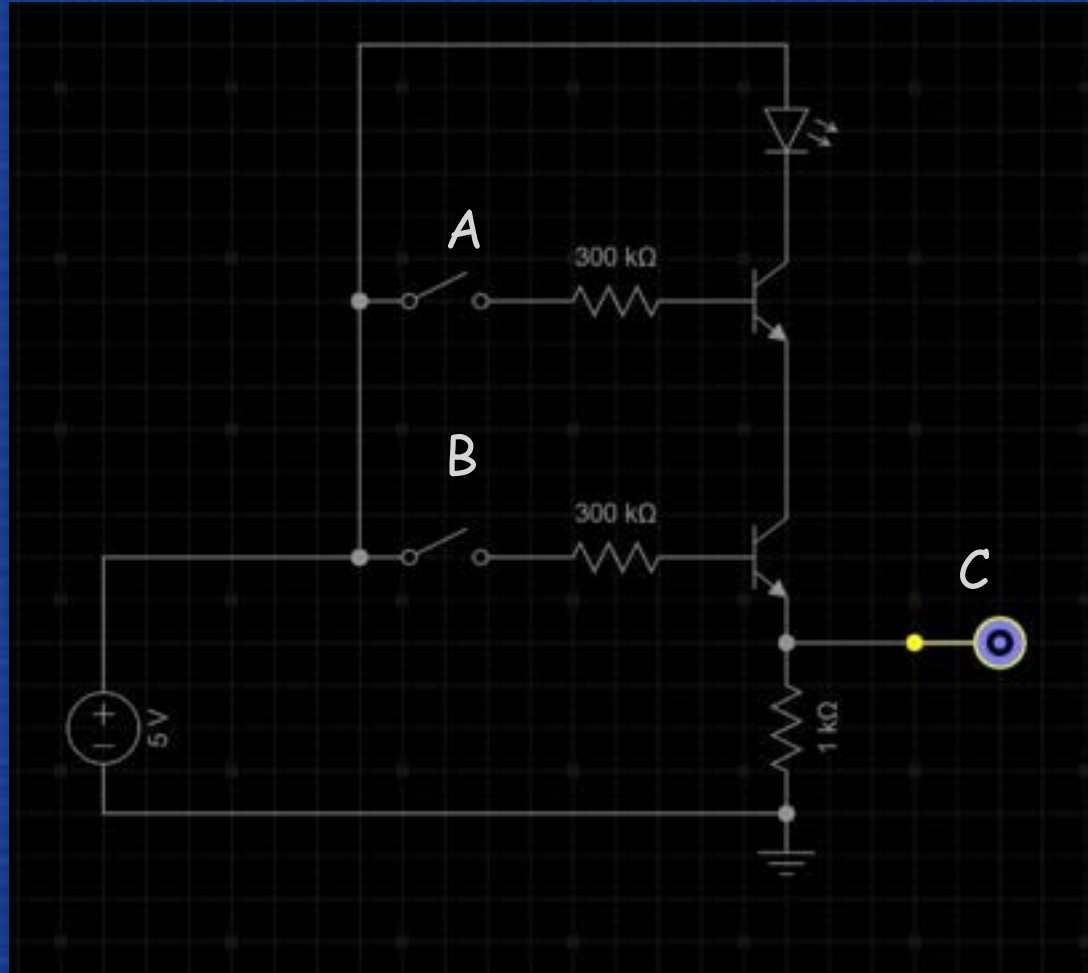
ELECTRICAL CHARACTERISTICS ($V_{CE} = 20V$, unless otherwise noted) (Continued)

Characteristics	Symbol	Min	Max	Unit
DC CHARACTERISTICS				
DC Current Gain	h_{FE}	20	—	—
$I_C = 0.1 mA, V_{CE} = 10 V, I_B = 10 \mu A$		20	—	
$I_C = 1.0 mA, V_{CE} = 10 V, I_B = 10 \mu A$		75	—	
$I_C = 10 mA, V_{CE} = 10 V, I_B = 10 \mu A$		20	—	
$I_C = 10 mA, V_{CE} = 10 V, I_B = 10 \mu A$		—	100	dB
$I_C = 100 mA, V_{CE} = 1.0 V, I_B = 10 \mu A$		50	—	
$I_C = 500 mA, V_{CE} = 0.2 V, I_B = 10 \mu A$		40	—	
Collector-Emitter Saturation Voltage ⁽¹⁾	$V_{CE(sat)}$	—	0.2	V
$I_C = 100 mA, I_B = 10 mA$		—	1.0	
$I_C = 500 mA, I_B = 50 mA$		—	1.0	
Base-Emitter Saturation Voltage ⁽¹⁾	$V_{BE(sat)}$	0.6	1.2	V
$I_C = 100 mA, I_B = 10 mA$		—	1.0	
$I_C = 500 mA, I_B = 50 mA$		—	1.0	
SMALL-SIGNAL CHARACTERISTICS				
Current Gain — Bandwidth Product	f_T	300	—	MHz
$I_C = 20 mA, V_{CE} = 20 V, f = 100 MHz$		—	0.0	pF
Output Capacitance	C_{out}	—	0.0	pF
$V_{CE} = 10 V, I_C = 0.1 mA$		—	20	pF
Input Capacitance	C_{in}	—	20	pF
$V_{CE} = 0.5 V, I_C = 0.1 mA$		—	20	pF
Input Impedance	Z_{in}	—	0.0	k Ω
$I_C = 1.0 mA, V_{CE} = 10 V, f = 1.0 MHz$		—	0.0	—
$I_C = 10 mA, V_{CE} = 10 V, f = 1.0 MHz$		—	0.0	—
Voltage Feedback Ratio	r_{re}	—	0.0	Ω
$I_C = 1.0 mA, V_{CE} = 10 V, f = 1.0 MHz$		—	0.0	—
$I_C = 10 mA, V_{CE} = 10 V, f = 1.0 MHz$		—	0.0	—
Small-Signal Current Gain	h_{FE}	50	300	—
$I_C = 1.0 mA, V_{CE} = 10 V, f = 1.0 MHz$		50	300	—
$I_C = 10 mA, V_{CE} = 10 V, f = 1.0 MHz$		50	300	—
Output Resistance	r_{out}	—	0.0	ohms
$I_C = 1.0 mA, V_{CE} = 10 V, f = 1.0 MHz$		—	0.0	—
$I_C = 10 mA, V_{CE} = 10 V, f = 1.0 MHz$		—	0.0	—
Minimum Base-Time Constant	τ_{bc}	—	100	ps
$I_C = 20 mA, V_{CE} = 20 V, f = 0.1 MHz$		—	100	—
Storage Time	t_{st}	—	1.0	ns
$I_C = 100 \mu A, V_{CE} = 10 V, I_B = 1.0 mA, f = 1.0 MHz$		—	1.0	—
SWITCHING CHARACTERISTICS				
Delay Time	$t_{d(on)}$	—	10	ns
$V_{CE} = 20 V, V_{BE} = 0.7 V, I_C = 10 mA, I_B = 10 \mu A$		—	10	—
Storage Time	$t_{d(off)}$	—	20	ns
$V_{CE} = 20 V, I_C = 10 mA, I_B = 10 \mu A$		—	20	—
Fall Time	t_{f}	—	20	ns
$V_{CE} = 20 V, I_C = 10 mA, I_B = 10 \mu A$		—	20	—

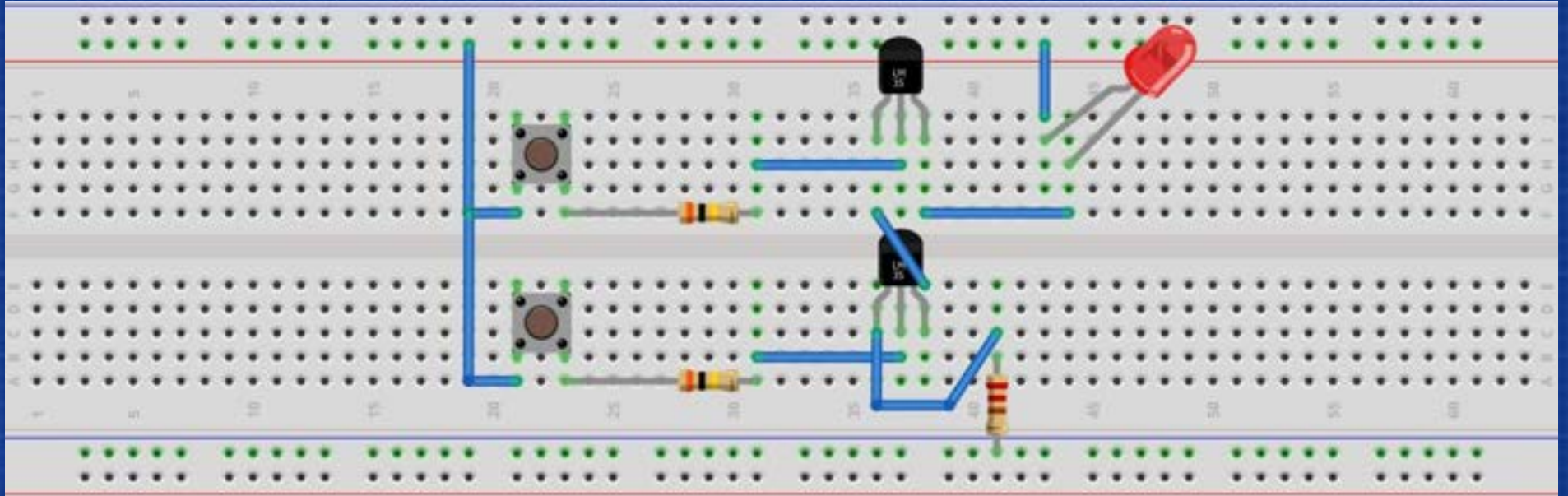
1. Pulse Test: Pulse Width $\leq 300 \mu s$, Duty Cycle $\leq 2.0\%$.
 2. f_T is defined as the frequency at which $|h_{FE}|$ extrapolated to unity.

LES TRANSISTORS

Que ce passe t-il ?

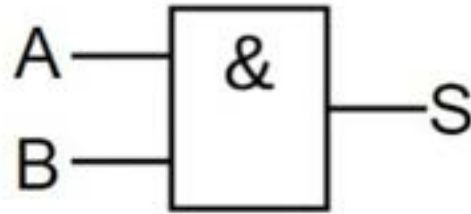


LES TRANSISTORS



Porte ET à transistors

LES TRANSISTORS

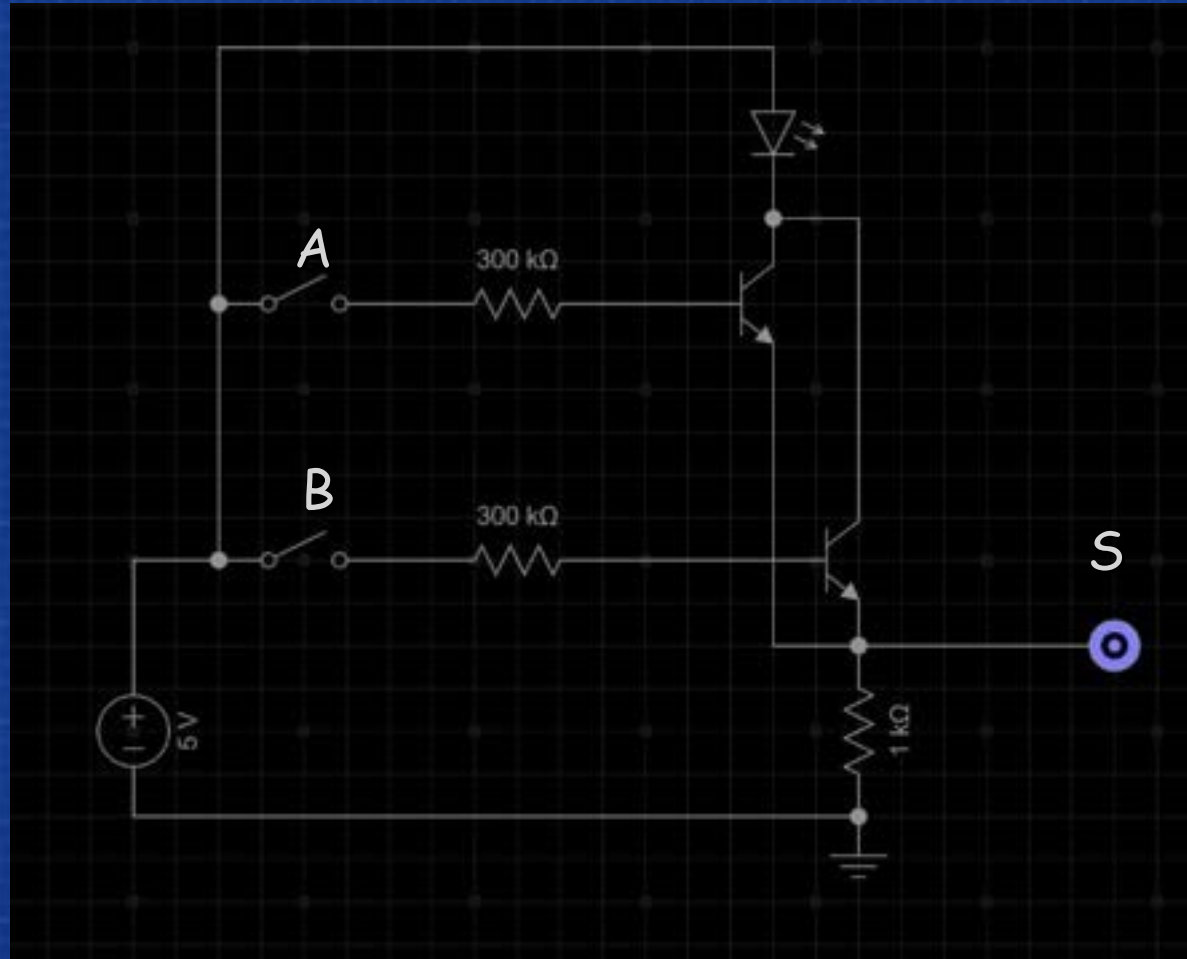


A	B	S
0	0	0
0	1	0
1	0	0
1	1	1

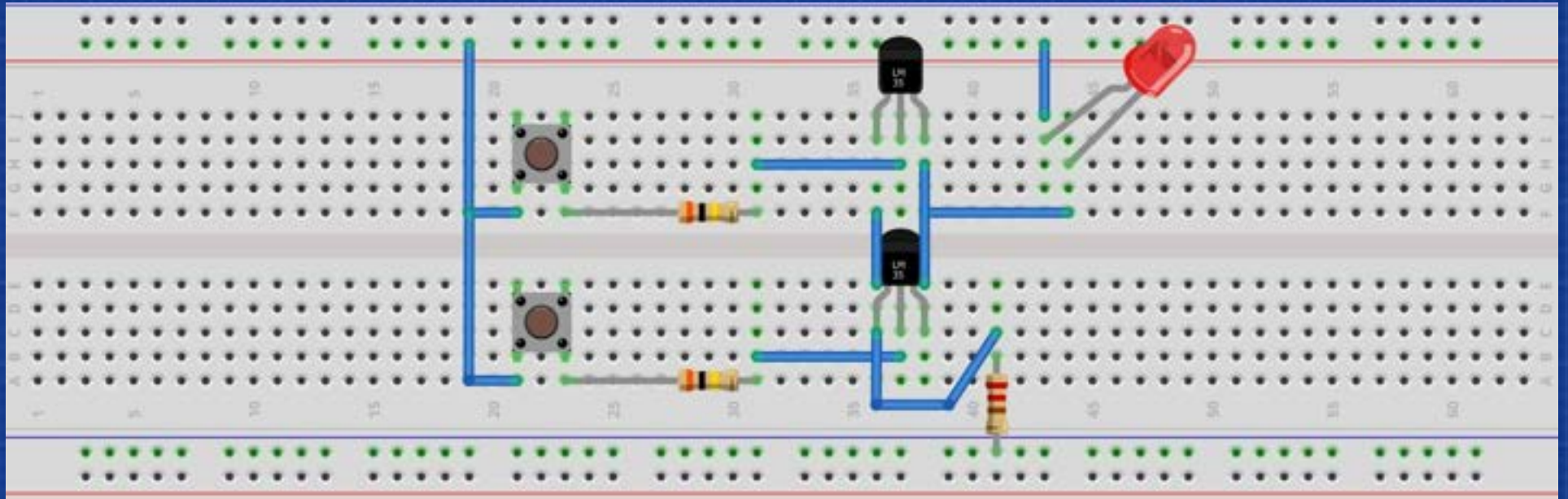
Porte ET logique combinatoire

LES TRANSISTORS

Que ce passe t-il ?

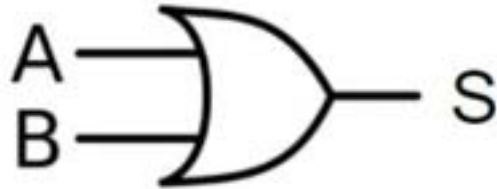
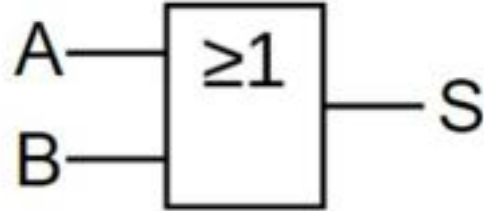


LES TRANSISTORS



Porte OU à transistors

LES TRANSISTORS



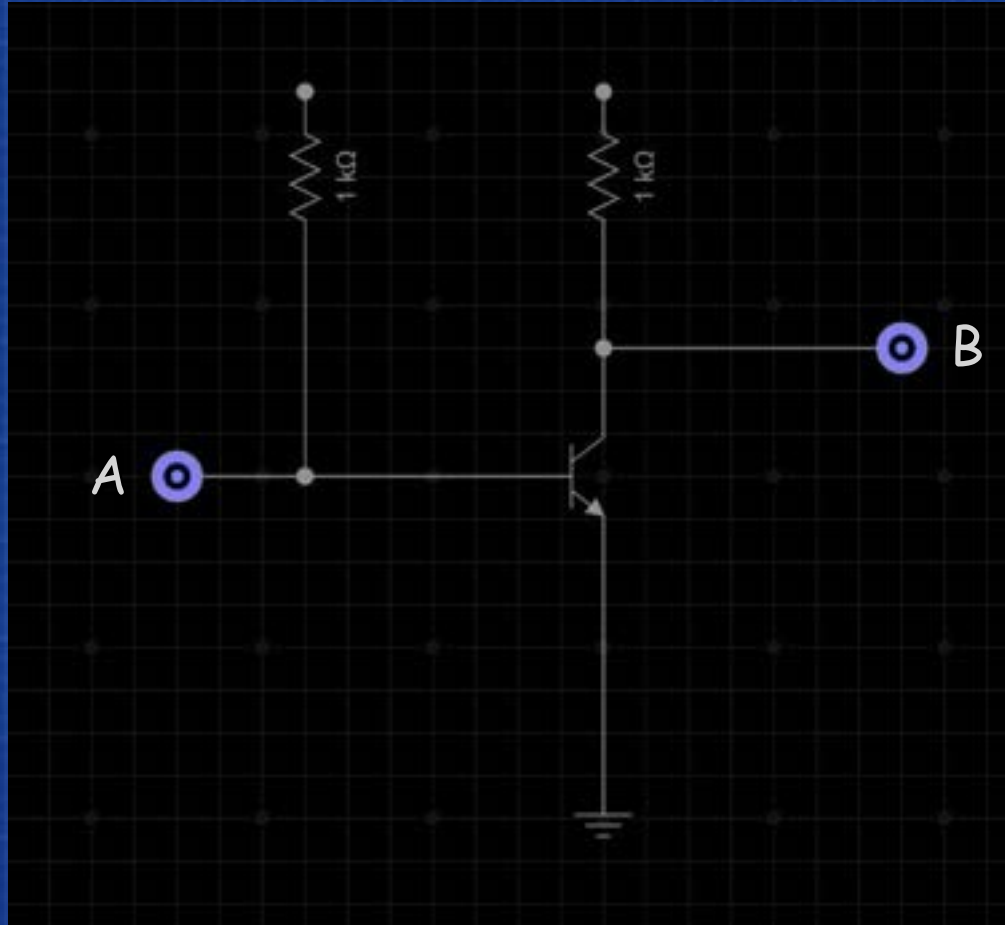
A	B	S
0	0	0
0	1	1
1	0	1
1	1	1

Porte OU logique combinatoire

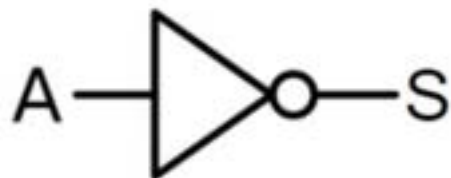
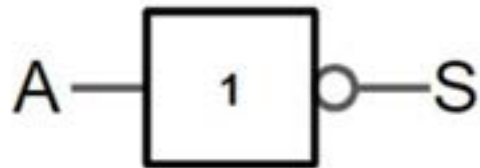
LES TRANSISTORS en circuit logique

Qu'est ce que c'est ?
Quelle fonction logique ?

A	B
0	1
1	0



LES TRANSISTORS



A	S
0	1
1	0

Inverseur logique

CIRCUITS LOGIQUES

Exercice :

Le voyant d'alarme s'allume quand :

- la fenetre ou la porte est ouverte et que l'interrupteur
« mise en route alarme est ON »

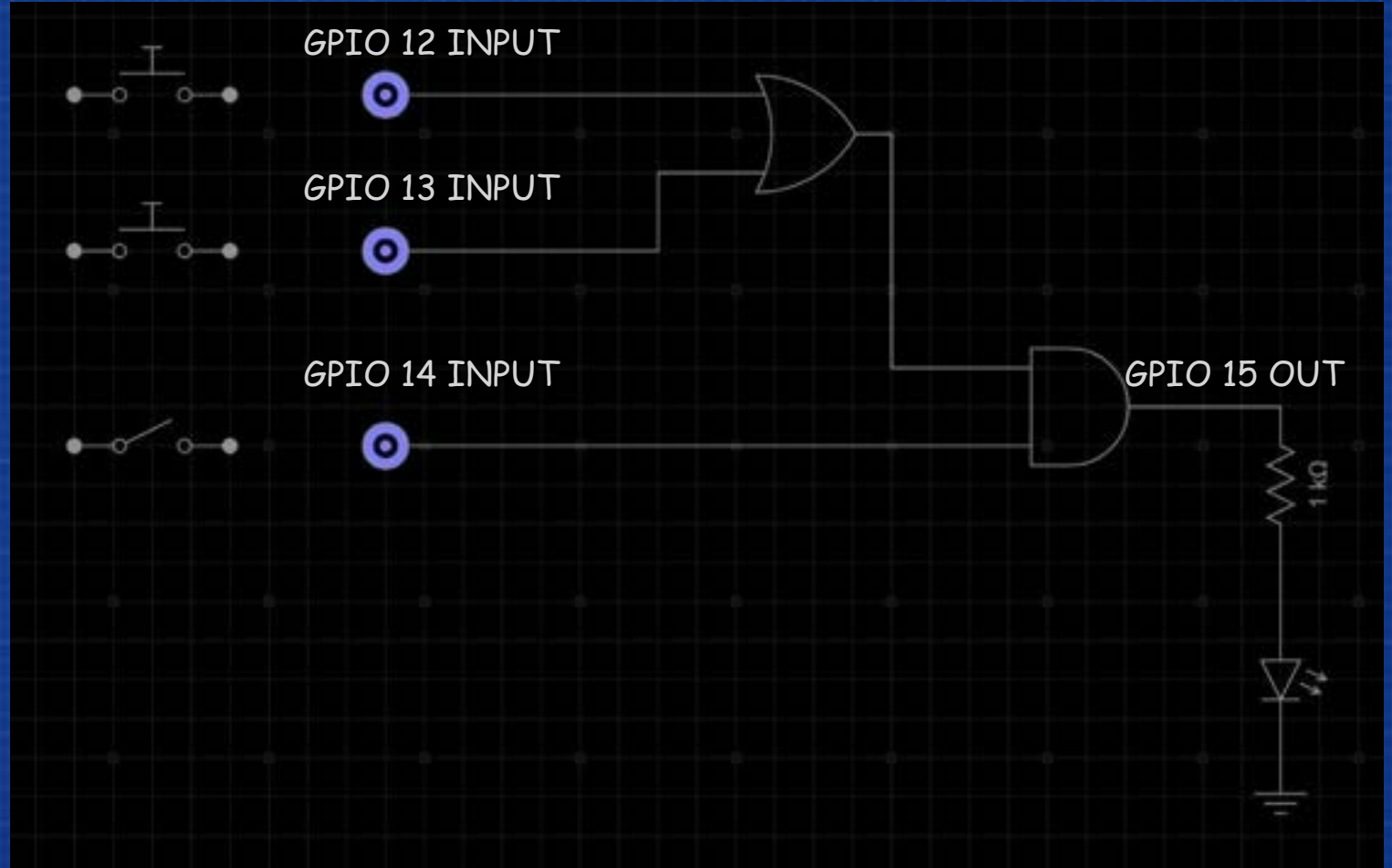
Faire le schema logique

CIRCUITS LOGIQUES

fenetre

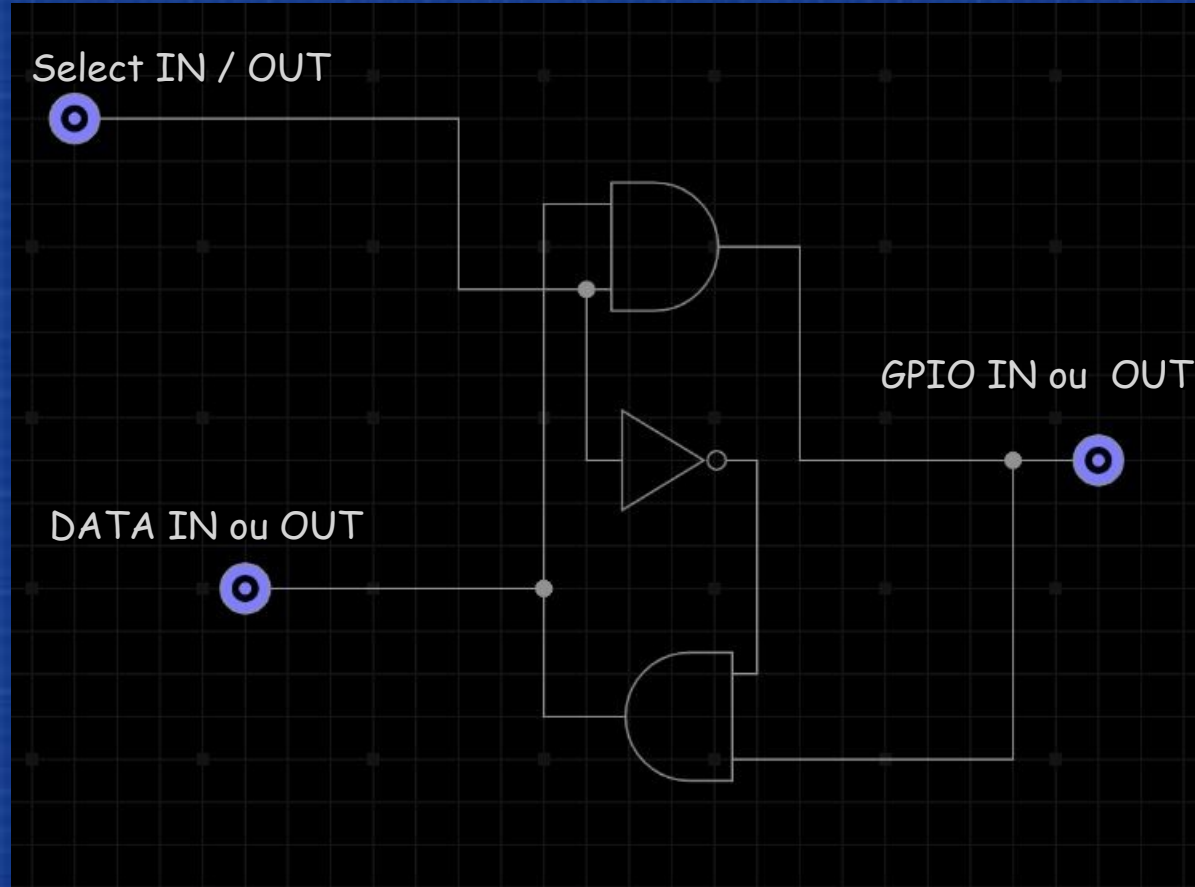
Porte

Alarme ON/OFF



CIRCUITS LOGIQUES

GPIO SETUP





GPIO SETUP

